

## DRV8711 步进电机控制器 IC

### 1 特性

- 脉宽调制 (PWM) 微步进电机驱动器
  - 内置 1/256 步长微步进分度器
  - 驱动外部 N 通道金属氧化物半导体场效应晶体管 (MOSFET)
  - 可选 STEP/DIR 引脚
  - 用于直流电机控制的可选脉宽调制 (PWM) 控制接口
- 灵活的衰减模式，其中包括自动混合衰减模式
- 具有可选反电势 (BEMF) 输出的停止转动检测
- 高度可配置 SPI 串行接口
- 内部基准和扭矩数模转换器 (DAC)
- 8V 至 52V 运行电源电压范围
- 可扩展输出电流
- 热增强型表面贴装式封装
- 能够处理 10mA 负载的 5V 稳压器
- 保护和诊断 特性
  - 过流保护 (OCP)
  - 过热关断 (OTS)
  - 欠压锁定 (UVLO)
  - 单独的故障情况指示位
  - 故障情况指示位

### 2 应用

- 办公自动化设备
- 工厂自动化
- 纺织机器
- 机器人

### 3 说明

DRV8711 器件是一款步进电机控制器，它使用外部 N 沟道 MOSFET 来驱动一个双极步进电机或两个刷式直流电机。该器件集成了一个微步进分度器，此分度器能够支持全步长至 1/256 步长的步进模式。

通过使用自适应消隐时间和包括自动混合衰减模式在内的多种不同的电流衰减模式，可实现非常平滑的运动系统配置。电机停止转动由一个可选反电势 (EMF) 输出报告。

一个简单的步进/方向或脉宽调制 (PWM) 接口可轻松连接至控制器电路。一个 SPI 串行接口被用来设定器件运行。输出电流（扭矩）、步进模式、衰减模式和堵转检测功能都可以通过 SPI 串行接口进行编程。

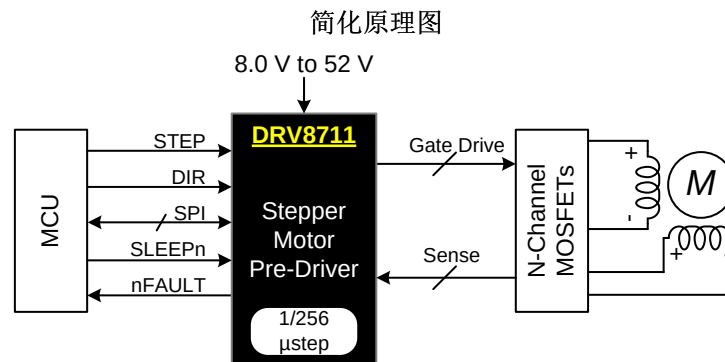
还提供了用于过流保护、短路保护、欠压锁定和过热保护的内部关断功能。故障状况通过 FAULTn 引脚进行指示，并且每种故障状况通过 SPI 由一个专用位进行报告。

DRV8711 采用 PowerPAD™38 引脚带有散热垫的散热薄型小外形尺寸 (HTSSOP) 封装（环保型：符合 RoHS 标准并且无铅/溴）。

器件信息<sup>(1)</sup>

| 器件型号    | 封装          | 封装尺寸（标称值）       |
|---------|-------------|-----------------|
| DRV8711 | HTSSOP (38) | 9.70mm × 4.40mm |

(1) 如需了解所有可用封装，请参阅产品说明书末尾的可订购产品附录。



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## 4 修订历史记录

注：之前版本的页码可能与当前版本有所不同。

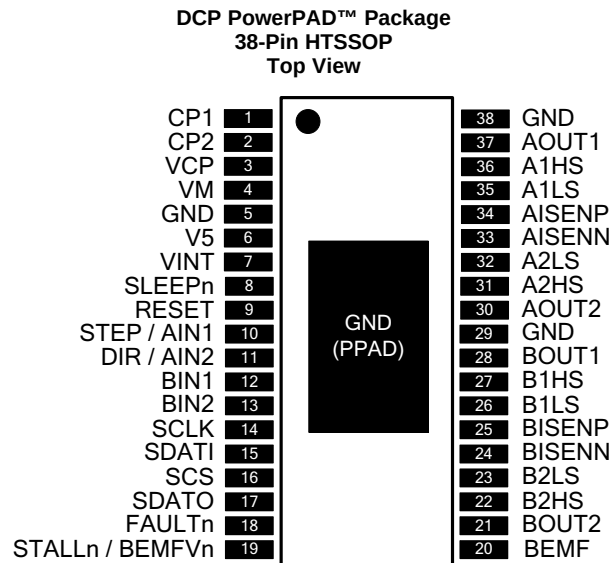
| Changes from Revision F (July 2016) to Revision G                                                                                                                           | Page |
|-----------------------------------------------------------------------------------------------------------------------------------------------------------------------------|------|
| • Changed the description of the SCS pin in the <i>Pin Functions</i> table .....                                                                                            | 3    |
| • Changed the maximum voltages for the charge pump voltage, high-side gate drive pin voltage, and phase node pin voltage in the <i>Absolute Maximum Ratings</i> table ..... | 5    |
| • Changed the OTS bit description in the STATUS register .....                                                                                                              | 29   |
| • Clarified UVLO bit operation when device is sleep mode .....                                                                                                              | 29   |

| Changes from Revision E (March 2015) to Revision F                                                       | Page |
|----------------------------------------------------------------------------------------------------------|------|
| • Clarified that the SMPLTH bit 10 is a write-only bit in the TORQUE register .....                      | 22   |
| • Changed the default values for the OCPH, OCPDEG, IDRIVEN, and IDRIVEP bits in the DRIVE register ..... | 28   |
| • 已添加 添加了接收文档更新通知 和社区资源 部分 .....                                                                         | 37   |

| Changes from Revision D (January 2014) to Revision E                                         | Page |
|----------------------------------------------------------------------------------------------|------|
| • 已添加 添加了 <i>ESD</i> 额定值表、特性说明部分、器件功能模式、应用和实施部分、电源相关建议部分、布局部分、器件和文档支持部分以及机械、封装和可订购信息部分 ..... | 1    |

| Changes from Revision C (December 2013) to Revision D       | Page |
|-------------------------------------------------------------|------|
| • Changed STATUS Register bit descriptions 3 through 5..... | 29   |

## 5 Pin Configuration and Functions



### Pin Functions

| PIN              |                 | I/O <sup>(1)</sup> | DESCRIPTION                   | EXTERNAL COMPONENTS OR CONNECTIONS                                                                                                   |
|------------------|-----------------|--------------------|-------------------------------|--------------------------------------------------------------------------------------------------------------------------------------|
| NAME             | NO.             |                    |                               |                                                                                                                                      |
| POWER AND GROUND |                 |                    |                               |                                                                                                                                      |
| GND              | 5, 29, 38, PPAD | —                  | Device ground                 | All pins must be connected to ground                                                                                                 |
| VM               | 4               | —                  | Bridge A power supply         | Connect to motor supply voltage. Bypass to GND with a 0.01-μF ceramic capacitor plus a 100-μF electrolytic capacitor.                |
| VINT             | 7               | —                  | Internal logic supply voltage | Logic supply voltage. Bypass to GND with a 1-μF 6.3-V X7R ceramic capacitor.                                                         |
| V5               | 6               | O                  | 5-V regulator output          | 5-V linear regulator output. Bypass to GND with a 0.1-μF 10-V X7R ceramic capacitor.                                                 |
| CP1              | 1               | IO                 | Charge pump flying capacitor  | Connect a 0.1-μF X7R capacitor between CP1 and CP2. Voltage rating must be greater than applied VM voltage.                          |
| CP2              | 2               | IO                 | Charge pump flying capacitor  |                                                                                                                                      |
| VCP              | 3               | IO                 | High-side gate drive voltage  | Connect a 1-μF 16-V X7R ceramic capacitor to VM                                                                                      |
| CONTROL          |                 |                    |                               |                                                                                                                                      |
| SLEEPn           | 8               | I                  | Sleep mode input              | Logic high to enable device, logic low to enter low-power sleep mode                                                                 |
| STEP/AIN1        | 10              | I                  | Step input/Bridge A IN1       | Indexer mode: Rising edge causes the indexer to move one step. External PWM mode: controls bridge A OUT1 Internal pulldown.          |
| DIR/AIN2         | 11              | I                  | Direction input/Bridge A IN2  | Indexer mode: Level sets the direction of stepping. External PWM mode: controls bridge A OUT2 Internal pulldown.                     |
| BIN1             | 12              | I                  | Bridge B IN1                  | Indexer mode: No function<br>External PWM mode: controls bridge B OUT1 Internal pulldown.                                            |
| BIN2             | 13              | I                  | Bridge B IN2                  | Indexer mode: No function<br>External PWM mode: controls bridge B OUT2 Internal pulldown.                                            |
| RESET            | 9               | I                  | Reset input                   | Active-high reset input initializes all internal logic and disables the H-bridge outputs. Internal pulldown.                         |
| SERIAL INTERFACE |                 |                    |                               |                                                                                                                                      |
| SCS              | 16              | I                  | Serial chip select input      | Active high to enable serial data transfer. Active low to complete the transaction. Internal pulldown.                               |
| SCLK             | 14              | I                  | Serial clock input            | Rising edge clocks data into part for write operations. Falling edge clocks data out of part for read operations. Internal pulldown. |

(1) Directions: I = input, O = output, OZ = 3-state output, OD = open-drain output, IO = input/output

**Pin Functions (continued)**

| PIN               |     | I/O <sup>(1)</sup> | DESCRIPTION            | EXTERNAL COMPONENTS OR CONNECTIONS                                                                                                                                                                  |
|-------------------|-----|--------------------|------------------------|-----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| NAME              | NO. |                    |                        |                                                                                                                                                                                                     |
| SDATI             | 15  | I                  | Serial data input      | Serial data input from controller. Internal pulldown.                                                                                                                                               |
| SDATO             | 17  | OD                 | Serial data output     | Serial data output to controller. Open-drain output requires external pullup.                                                                                                                       |
| <b>STATUS</b>     |     |                    |                        |                                                                                                                                                                                                     |
| STALLn/<br>BEMFVn | 19  | OD                 | Stall/Back EMF valid   | Internal stall detect mode: logic low when motor stall detected.<br>External stall detect mode: Active low when valid back EMF measurement is ready.<br>Open-drain output requires external pullup. |
| FAULTn            | 18  | OD                 | Fault                  | Logic low when in fault condition. Open-drain output requires external pullup.<br>Faults: OCP, PDF, OTS, UVLO                                                                                       |
| BEMF              | 20  | O                  | Back EMF               | Analog output voltage represents motor back EMF. Place a 1-nF low-leakage capacitor to ground on this pin.                                                                                          |
| <b>OUTPUTS</b>    |     |                    |                        |                                                                                                                                                                                                     |
| A1HS              | 36  | O                  | Bridge A out 1 HS gate | Connect to gate of HS FET for bridge A out 1                                                                                                                                                        |
| AOUT1             | 37  | I                  | Bridge A output 1      | Connect to output node of external FETs of bridge A out 1                                                                                                                                           |
| A1LS              | 35  | O                  | Bridge A out 1 LS gate | Connect to gate of LS FET for bridge A out 1                                                                                                                                                        |
| A2HS              | 31  | O                  | Bridge A out 2 HS gate | Connect to gate of HS FET for bridge A out 2                                                                                                                                                        |
| AOUT2             | 30  | I                  | Bridge A output 2      | Connect to output node of external FETs of bridge A out 2                                                                                                                                           |
| A2LS              | 32  | O                  | Bridge A out 2 LS gate | Connect to gate of LS FET for bridge A out 2                                                                                                                                                        |
| AISENP            | 34  | I                  | Bridge A Isense + in   | Connect to current sense resistor for bridge A                                                                                                                                                      |
| AISENN            | 33  | I                  | Bridge A Isense – in   | Connect to ground at current sense resistor for bridge A                                                                                                                                            |
| B1HS              | 27  | O                  | Bridge B out 1 HS gate | Connect to gate of HS FET for bridge B out 1                                                                                                                                                        |
| BOUT1             | 28  | I                  | Bridge B output 1      | Connect to output node of external FETs of bridge B out 1                                                                                                                                           |
| B1LS              | 26  | O                  | Bridge B out 1 LS gate | Connect to gate of LS FET for bridge B out 1                                                                                                                                                        |
| B2HS              | 22  | O                  | Bridge B out 2 HS gate | Connect to gate of HS FET for bridge B out 2                                                                                                                                                        |
| BOUT2             | 21  | I                  | Bridge B output 2      | Connect to output node of external FETs of bridge B out 2                                                                                                                                           |
| B2LS              | 23  | O                  | Bridge B out 2 LS gate | Connect to gate of LS FET for bridge B out 2                                                                                                                                                        |
| BISENP            | 25  | I                  | Bridge B Isense + in   | Connect to current sense resistor for bridge B                                                                                                                                                      |
| BISENN            | 24  | I                  | Bridge B Isense – in   | Connect to ground at current sense resistor for bridge B                                                                                                                                            |

## 6 Specifications

### 6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)<sup>(1)(2)(3)</sup>

|                                                                                                                      | MIN  | MAX      | UNIT |
|----------------------------------------------------------------------------------------------------------------------|------|----------|------|
| Power supply voltage                                                                                                 | −0.6 | 60       | V    |
| Charge pump voltage (CP2, VCP)                                                                                       | −0.6 | VM + 12  | V    |
| Charge pump voltage (CP1)                                                                                            | −0.6 | VM + 0.6 | V    |
| 5-V regulator voltage (V5)                                                                                           | −0.6 | 5.5      | V    |
| Internal regulator voltage (VINT)                                                                                    | −0.6 | 2        | V    |
| Digital pin voltage (SLEEPn, RESET, STEP/AIN1, DIR/AIN2, BIN1, BIN2, SCS, SCLK, SDAT1, SDATO, FAULTn, STALLn/BEMFVn) | −0.6 | 5.5      | V    |
| High-side gate drive pin voltage (A1HS, A2HS, B1HS, B2HS)                                                            | −0.6 | VM + 12  | V    |
| Low-side gate drive pin voltage (A1LS, A2LS, B1LS, B2LS)                                                             | −0.6 | 12       | V    |
| Phase node pin voltage (AOUT1, AOUT2, BOUT1, BOUT2)                                                                  | −0.6 | VM + 0.6 | V    |
| ISENSEx pin voltage (AISENP, AISENN, BISENP, BISENN)                                                                 | −0.7 | 0.7      | V    |
| BEMF pin voltage (BEMF)                                                                                              | −0.6 | 5.5      | V    |
| Operating virtual junction temperature, T <sub>J</sub>                                                               | −40  | 150      | °C   |
| Storage temperature, T <sub>stg</sub>                                                                                | −60  | 150      | °C   |

- (1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) All voltage values are with respect to network ground terminal.
- (3) Power dissipation and thermal limits must be observed.

### 6.2 ESD Ratings

|                                            | VALUE                                                                          | UNIT  |
|--------------------------------------------|--------------------------------------------------------------------------------|-------|
| V <sub>(ESD)</sub> Electrostatic discharge | Human body model (HBM), per ANSI/ESDA/JEDEC JS-001 <sup>(1)</sup>              | ±4000 |
|                                            | Charged device model (CDM), per JEDEC specification JESD22-C101 <sup>(2)</sup> | ±1500 |

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
- (2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

### 6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

|                                              | MIN | NOM | MAX | UNIT |
|----------------------------------------------|-----|-----|-----|------|
| V <sub>M</sub> Motor power supply voltage    | 8   |     | 52  | V    |
| I <sub>VS</sub> V5 external load current     | 0   |     | 10  | mA   |
| T <sub>A</sub> Operating ambient temperature | −40 |     | 85  | °C   |

### 6.4 Thermal Information

| THERMAL METRIC <sup>(1)</sup> |                                              | DRV8711      | UNIT |
|-------------------------------|----------------------------------------------|--------------|------|
|                               |                                              | DCP (HTSSOP) |      |
|                               |                                              | 38 PINS      |      |
| R <sub>θJA</sub>              | Junction-to-ambient thermal resistance       | 32.7         | °C/W |
| R <sub>θJC(top)</sub>         | Junction-to-case (top) thermal resistance    | 17.2         | °C/W |
| R <sub>θJB</sub>              | Junction-to-board thermal resistance         | 14.3         | °C/W |
| ψ <sub>JT</sub>               | Junction-to-top characterization parameter   | 0.5          | °C/W |
| ψ <sub>JB</sub>               | Junction-to-board characterization parameter | 14.1         | °C/W |
| R <sub>θJC(bot)</sub>         | Junction-to-case (bottom) thermal resistance | 0.9          | °C/W |

- (1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics](#) application report.

## 6.5 Electrical Characteristics

over operating free-air temperature range (unless otherwise noted)

| PARAMETER                                           |                                                                           | TEST CONDITIONS                              | MIN | TYP   | MAX  | UNIT |
|-----------------------------------------------------|---------------------------------------------------------------------------|----------------------------------------------|-----|-------|------|------|
| POWER SUPPLIES                                      |                                                                           |                                              |     |       |      |      |
| I <sub>VM</sub>                                     | VM operating supply current                                               | VM = 24 V                                    |     | 17    | 20   | mA   |
| I <sub>VMQ</sub>                                    | VM sleep mode supply current                                              | VM = 24 V, SLEEPn = 0, T <sub>A</sub> = 25°C |     | 65    | 98   | μA   |
| V <sub>UVLO</sub>                                   | VM undervoltage lockout voltage                                           | VM rising                                    |     | 7.1   | 8    | V    |
|                                                     |                                                                           | VM falling                                   |     | 6.3   |      |      |
| INTERNAL LINEAR REGULATORS                          |                                                                           |                                              |     |       |      |      |
| V <sub>5</sub>                                      | V5 output voltage                                                         | VM ≥ 12 V, I <sub>OUT</sub> = 1 mA – 10 mA   | 4.8 | 5     | 5.2  | V    |
| V <sub>INT</sub>                                    | VINT voltage                                                              | No external load – reference only            | 1.7 | 1.8   | 1.9  | V    |
| LOGIC-LEVEL INPUTS                                  |                                                                           |                                              |     |       |      |      |
| V <sub>IL</sub>                                     | Input low voltage                                                         |                                              |     |       | 0.8  | V    |
| V <sub>IH</sub>                                     | Input high voltage                                                        |                                              | 1.5 |       |      | V    |
| V <sub>HYS</sub>                                    | Input hysteresis voltage                                                  |                                              |     | 300   |      | mV   |
| I <sub>IL</sub>                                     | Input low current                                                         | V <sub>IN</sub> = 0 V                        | –5  |       | 5    | μA   |
| I <sub>IH</sub>                                     | Input high current                                                        | V <sub>IN</sub> = 5 V                        | 30  | 50    | 70   | μA   |
| SDATAO, STALLn, FAULTn OUTPUTS (OPEN-DRAIN OUTPUTS) |                                                                           |                                              |     |       |      |      |
| V <sub>OL</sub>                                     | Output low voltage                                                        | I <sub>O</sub> = 5 mA                        |     |       | 0.5  | V    |
| I <sub>OH</sub>                                     | Output high leakage current                                               | V <sub>O</sub> = 3.3 V                       |     |       | 1    | μA   |
| MOSFET DRIVERS                                      |                                                                           |                                              |     |       |      |      |
| V <sub>OUTH</sub>                                   | High-side gate drive output voltage                                       | VM = 24 V, I <sub>O</sub> = 100 μA           |     | VM+10 |      | V    |
| V <sub>OUTL</sub>                                   | Low-side gate drive output voltage                                        | VM = 24 V, I <sub>O</sub> = 100 μA           |     | 10    |      | V    |
| t <sub>DEAD</sub>                                   | Output dead time digital delay (dead time is enforced in analog circuits) | DTIME = 00                                   |     | 400   |      | ns   |
|                                                     |                                                                           | DTIME = 01                                   |     | 450   |      |      |
|                                                     |                                                                           | DTIME = 10                                   |     | 650   |      |      |
|                                                     |                                                                           | DTIME = 11                                   |     | 850   |      |      |
| I <sub>OUTH</sub>                                   | Peak output current gate drive (source)                                   | IDRIVEP = 00                                 |     | 50    |      | mA   |
|                                                     |                                                                           | IDRIVEP = 01                                 |     | 100   |      |      |
|                                                     |                                                                           | IDRIVEP = 10                                 |     | 150   |      |      |
|                                                     |                                                                           | IDRIVEP = 11                                 |     | 200   |      |      |
| I <sub>OUTI</sub>                                   | Peak output current gate drive (sink)                                     | IDRIVEN = 00                                 |     | 100   |      | mA   |
|                                                     |                                                                           | IDRIVEN = 01                                 |     | 150   |      |      |
|                                                     |                                                                           | IDRIVEN = 10                                 |     | 200   |      |      |
|                                                     |                                                                           | IDRIVEN = 11                                 |     | 400   |      |      |
| t <sub>DRIVE</sub>                                  | Peak current drive time (source)                                          | TDRIVEP = 00                                 |     | 250   |      | ns   |
|                                                     |                                                                           | TDRIVEP = 01                                 |     | 500   |      |      |
|                                                     |                                                                           | TDRIVEP = 10                                 |     | 1000  |      |      |
|                                                     |                                                                           | TDRIVEP = 11                                 |     | 2000  |      |      |
| t <sub>DRIVE</sub>                                  | Peak current drive time (sink)                                            | TDRIVEN = 00                                 |     | 250   |      | ns   |
|                                                     |                                                                           | TDRIVEN = 01                                 |     | 500   |      |      |
|                                                     |                                                                           | TDRIVEN = 10                                 |     | 1000  |      |      |
|                                                     |                                                                           | TDRIVEN = 11                                 |     | 2000  |      |      |
| MOTOR DRIVER                                        |                                                                           |                                              |     |       |      |      |
| t <sub>OFF</sub>                                    | PWM off time adjustment range                                             | Set by TOFF register                         | 0.5 |       | 128  | μs   |
| t <sub>BLANK</sub>                                  | Current sense blanking time                                               | Set by TBLANK register                       | 0.5 |       | 5.12 | μs   |

## Electrical Characteristics (continued)

over operating free-air temperature range (unless otherwise noted)

| PARAMETER                       |                                                                         | TEST CONDITIONS                       | MIN  | TYP  | MAX  | UNIT    |
|---------------------------------|-------------------------------------------------------------------------|---------------------------------------|------|------|------|---------|
| <b>PROTECTION CIRCUITS</b>      |                                                                         |                                       |      |      |      |         |
| $V_{OCP}$                       | Overcurrent protection trip level<br>(Voltage drop across external FET) | OCPH = 00                             | 160  | 250  | 320  | mV      |
|                                 |                                                                         | OCPH = 01                             | 380  | 500  | 580  |         |
|                                 |                                                                         | OCPH = 10                             | 620  | 750  | 850  |         |
|                                 |                                                                         | OCPH = 11                             | 840  | 1000 | 1200 |         |
| $t_{TSD}$                       | Thermal shutdown temperature <sup>(1)</sup>                             | Die temperature                       | 150  | 160  | 180  | °C      |
| $t_{HYS}$                       | Thermal shutdown hysteresis                                             |                                       |      | 20   |      | °C      |
| <b>CURRENT SENSE AMPLIFIERS</b> |                                                                         |                                       |      |      |      |         |
| $A_V$                           | Gain                                                                    | ISGAIN = 00                           |      | 5    |      | V/V     |
|                                 |                                                                         | ISGAIN = 01                           |      | 10   |      |         |
|                                 |                                                                         | ISGAIN = 10                           |      | 20   |      |         |
|                                 |                                                                         | ISGAIN = 11                           |      | 40   |      |         |
| $t_{SET}$                       | Settling time (to $\pm 1\%$ )                                           | ISGAIN = 00, $\Delta V_{IN} = 400$ mV |      | 150  |      | ns      |
|                                 |                                                                         | ISGAIN = 01, $\Delta V_{IN} = 200$ mV |      | 300  |      |         |
|                                 |                                                                         | ISGAIN = 10, $\Delta V_{IN} = 100$ mV |      | 600  |      |         |
|                                 |                                                                         | ISGAIN = 11, $\Delta V_{IN} = 50$ mV  |      | 1.2  |      | $\mu$ s |
| $V_{OFS}$                       | Offset voltage                                                          | ISGAIN = 00, input shorted            |      |      | 4    | mV      |
| $V_{IN}$                        | Input differential voltage range                                        |                                       | –600 |      | 600  | mV      |
| <b>CURRENT CONTROL DACs</b>     |                                                                         |                                       |      |      |      |         |
|                                 | Resolution                                                              |                                       |      | 256  |      | steps   |
|                                 | Full-scale step response                                                | 10% to 90%                            |      |      | 5    | $\mu$ s |
| $V_{REF}$                       | Full-scale (reference) voltage                                          |                                       | 2.50 | 2.75 | 3    | V       |

(1) Not tested in production; ensured by design.

## 6.6 SPI Timing Requirements

over operating free-air temperature range (unless otherwise noted) (see [Figure 1](#))

| NO. |                 |                                                                      | MIN | NOM | MAX | UNIT    |
|-----|-----------------|----------------------------------------------------------------------|-----|-----|-----|---------|
| 1   | $t_{CYC}$       | Clock cycle time                                                     | 250 |     |     | ns      |
| 2   | $t_{CLKH}$      | Clock high time                                                      | 25  |     |     | ns      |
| 3   | $t_{CLKL}$      | Clock low time                                                       | 25  |     |     | ns      |
| 4   | $t_{SU(SDATI)}$ | Setup time, SDATI to SCLK                                            | 5   |     |     | ns      |
| 5   | $t_{H(SDATI)}$  | Hold time, SDATI to SCLK                                             | 1   |     |     | ns      |
| 6   | $t_{SU(SCS)}$   | Setup time, SCS to SCLK                                              | 5   |     |     | ns      |
| 7   | $t_{H(SCS)}$    | Hold time, SCS to SCLK                                               | 1   |     |     | ns      |
| 8   | $t_{L(SCS)}$    | Inactive time, SCS (between writes and reads)                        | 100 |     |     | ns      |
| 9   | $t_{D(SDATO)}$  | Delay time, SCLK to SDATO (during read)                              |     |     | 10  | ns      |
|     | $t_{SLEEP}$     | Wake time (SLEEPn inactive to high-side gate drive enabled)          |     |     | 1   | ms      |
|     | $t_{RESET}$     | Delay from power up or RESETn high until serial interface functional |     |     | 10  | $\mu$ s |

## 6.7 Indexer Timing Requirements

over operating free-air temperature range (unless otherwise noted) (see [Figure 2](#))

| NO. |                                                          | MIN | NOM | MAX | UNIT          |
|-----|----------------------------------------------------------|-----|-----|-----|---------------|
| 1   | $f_{\text{STEP}}$ Step frequency                         |     |     | 250 | kHz           |
| 2   | $t_{\text{WH(STEP)}}$ Pulse duration, STEP high          | 1.9 |     |     | $\mu\text{s}$ |
| 3   | $t_{\text{WL(STEP)}}$ Pulse duration, STEP low           | 1.9 |     |     | $\mu\text{s}$ |
| 4   | $t_{\text{SU(STEP)}}$ Setup time, command to STEP rising | 200 |     |     | ns            |
| 5   | $t_{\text{H(STEP)}}$ Hold time, command to STEP rising   | 200 |     |     | ns            |

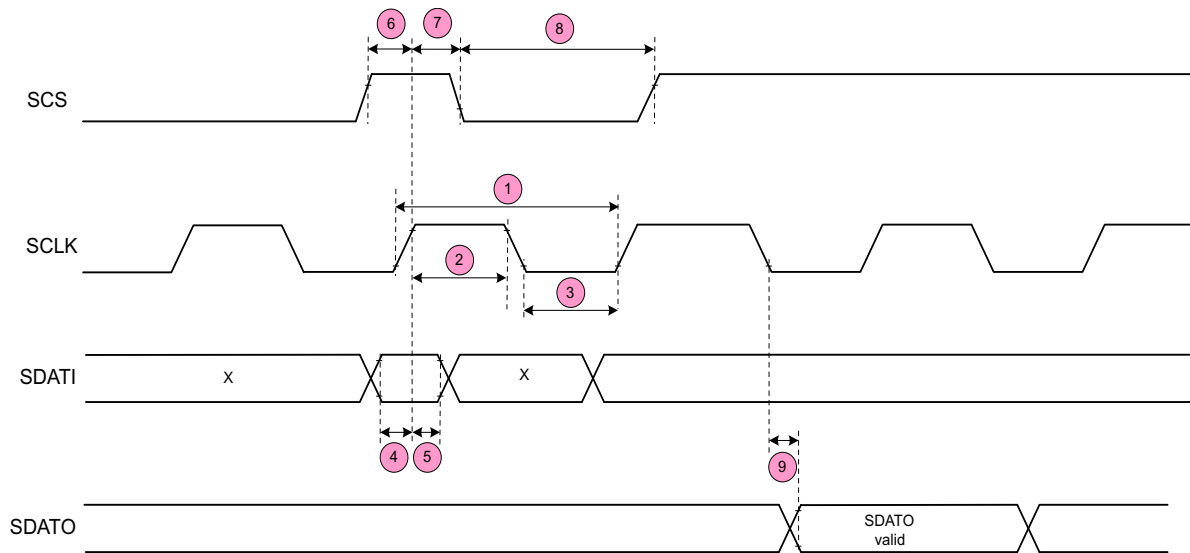


**Figure 1. SPI Timing**

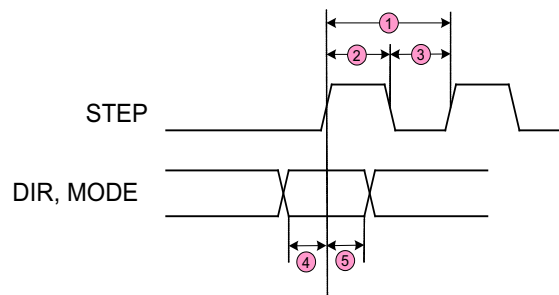


**Figure 2. Indexer Timing**

## 6.8 Typical Characteristics

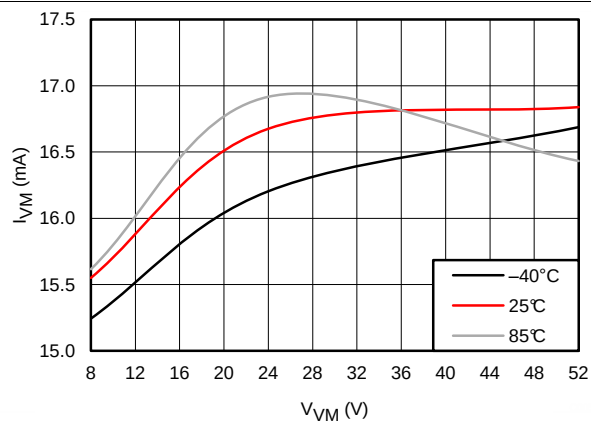


Figure 3. Operating Current

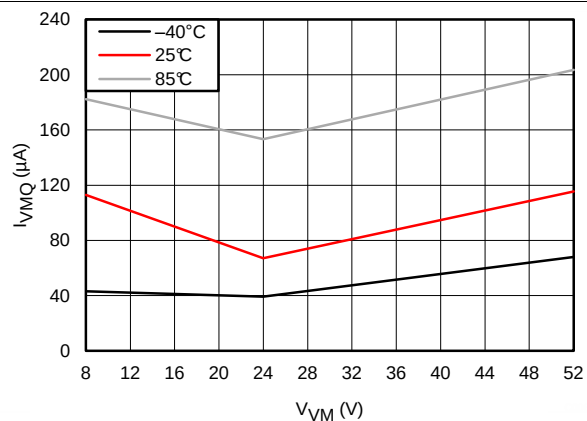


Figure 4. Sleep Current

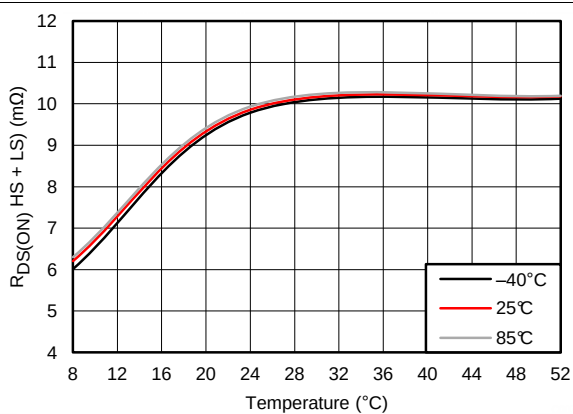


Figure 5. VCP Minus VM

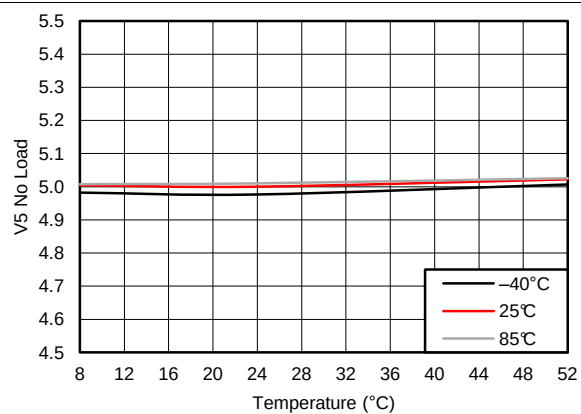


Figure 6. V5 No Load

## 7 Detailed Description

### 7.1 Overview

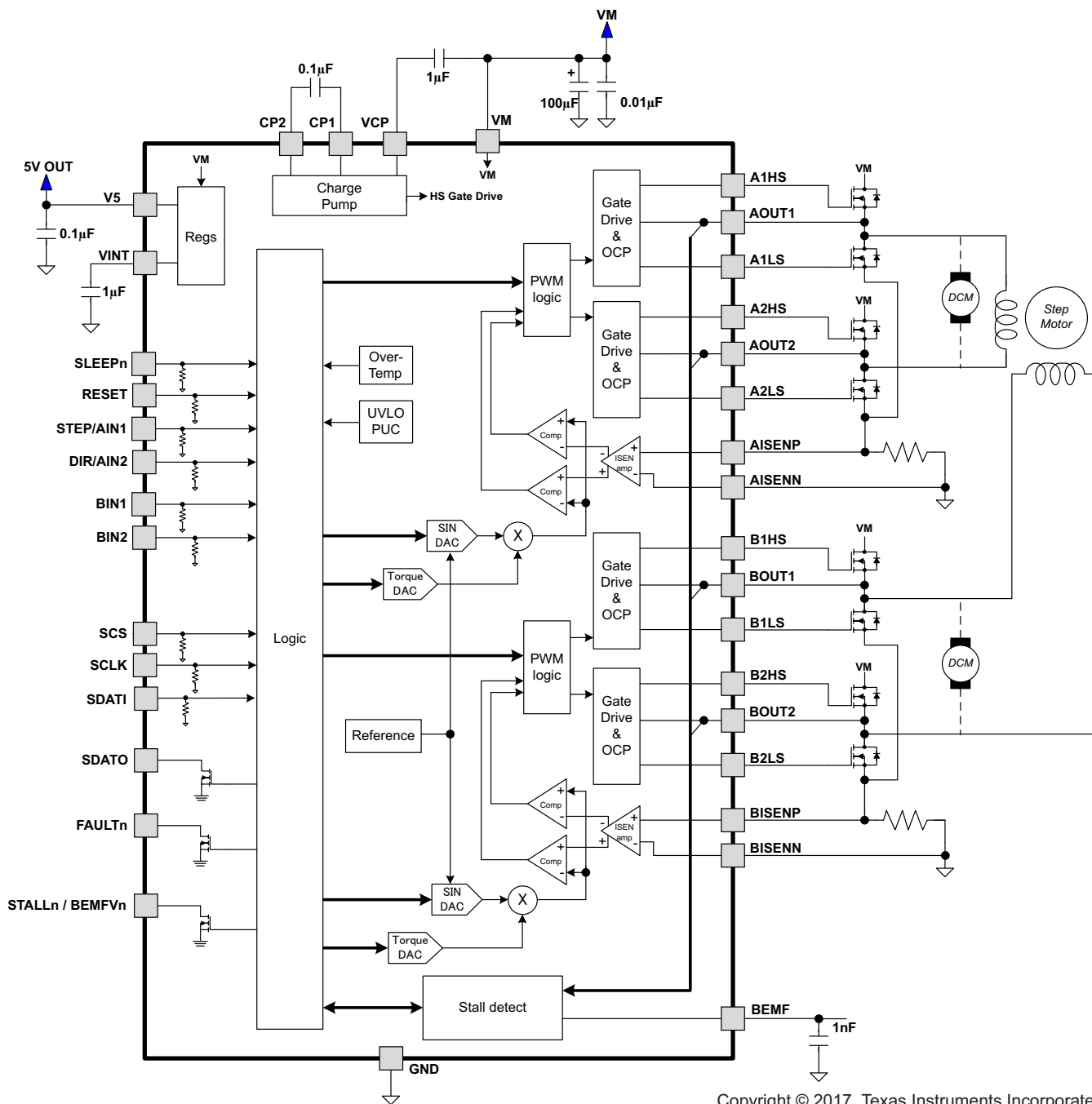
The DRV8711 device is a stepper motor controller that uses external N-channel MOSFETs to drive a bipolar stepper motor or two brushed DC motors. A microstepping indexer is integrated, which is capable of step modes from full step to 1/256-step.

An ultra-smooth motion profile can be achieved using adaptive blanking time, adjustable decay times, and various current decay modes, including an auto-mixed decay mode. When microstepping, motor stall can be reported with an optional back-EMF output.

A simple step/direction or PWM interface allows easy interfacing to controller circuits. A SPI serial interface is used to program the device operation. Output current (torque), step mode, decay mode, and stall detection functions are all programmable through a SPI serial interface.

Internal shutdown functions are provided for overcurrent protection, short-circuit protection, undervoltage lockout, and overtemperature. Fault conditions are indicated through a FAULTn pin, and each fault condition is reported through a dedicated bit through SPI.

## 7.2 Functional Block Diagram



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## 7.3 Feature Description

Table 1 lists the critical components for the device.

**Table 1. Critical Components**

| PIN  | NAME          | COMPONENT                                                                                               |
|------|---------------|---------------------------------------------------------------------------------------------------------|
| 4    | VM            | 100- $\mu$ F electrolytic rated for VM voltage to GND 0.01- $\mu$ F ceramic rated for VM voltage to GND |
| 3    | VCP           | 1- $\mu$ F ceramic X7R rated 16 V to VCP                                                                |
| 1, 2 | CP1, CP2      | 0.1- $\mu$ F rated for VM + 12 V between these pins                                                     |
| 6    | V5            | 0.1- $\mu$ F ceramic X7R rated 6.3 V to GND                                                             |
| 7    | VINT          | 1- $\mu$ F ceramic X7R rated 6.3 V to GND                                                               |
| 17   | SDATO         | Requires external pullup to logic supply                                                                |
| 18   | FAULTn        | Requires external pullup to logic supply                                                                |
| 19   | STALLn/BEMFVn | Requires external pullup to logic supply                                                                |
| 20   | BEMF          | 1-nF low-leakage capacitor to GND                                                                       |

### 7.3.1 PWM Motor Drivers

The DRV8711 contains two H-bridge motor predrivers with current control PWM circuitry. More detailed descriptions of the subblocks are described in the following sections.

### 7.3.2 Direct PWM Input Mode

Direct PWM mode is selected by setting the PWMMODE bit in the OFF register. In direct PWM input mode, the AIN1, AIN2, BIN1, and BIN2 directly control the state of the output drivers. This allows for driving up to two brushed DC motors. The logic is shown in Table 2:

**Table 2. Direct PWM Input Mode Logic**

| xIN1 | xIN2 | xOUT1 | xOUT2 | OPERATION               |
|------|------|-------|-------|-------------------------|
| 0    | 0    | Z     | Z     | Asynchronous Fast Decay |
| 0    | 1    | L     | H     | Reverse Drive           |
| 1    | 0    | H     | L     | Forward Drive           |
| 1    | 1    | L     | L     | Slow Decay              |

If mixed or auto-mixed decay modes are used, they will apply to every cycle, because current change information is not available.

In direct PWM mode, the current control circuitry is still active. The full-scale VREF is set to 2.75 V. The TORQUE register may be used to scale this value, and the ISEN sense amp gain may still be set using the ISGAIN bits of the CTRL register.

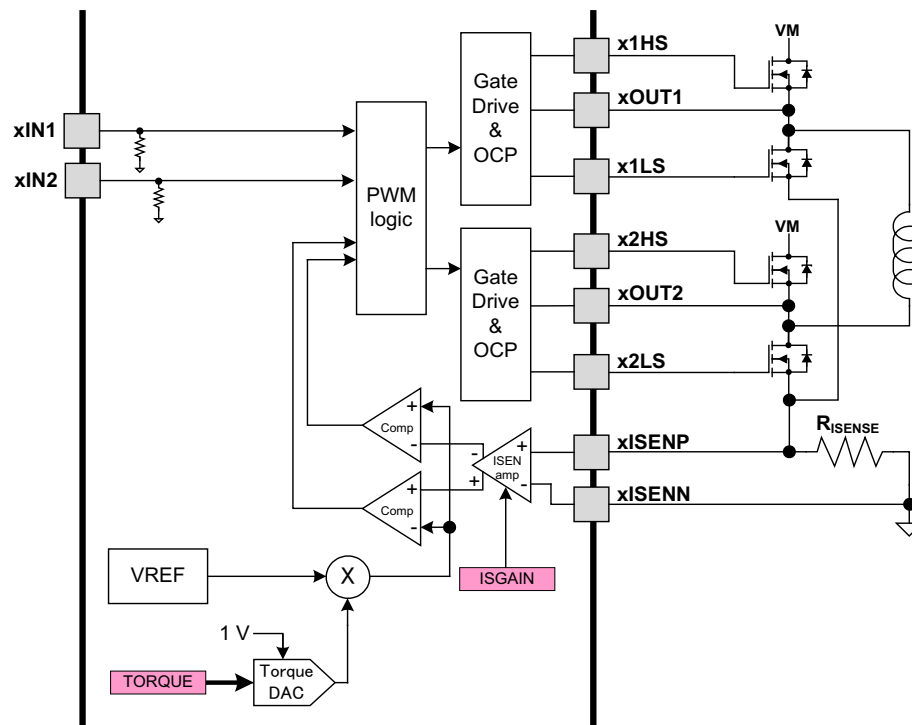


**Figure 7. Direct PWM Input Mode**

The current through the motor windings is regulated by an adjustable fixed-off-time PWM current regulation circuit. When an H-bridge is enabled, current rises through the winding at a rate dependent on the DC voltage and inductance of the winding and the magnitude of the back EMF present. Once the current hits the current chopping threshold, the bridge disables the current for a fixed period of time, which is programmable between 500 ns and 128  $\mu$ s by writing to the TOFF bits in the OFF register. After the off time expires, the bridge is re-enabled, starting another PWM cycle.

The chopping current is set by a comparator which compares the voltage across a current sense resistor connected to the xISENx pins, multiplied by the gain of the current sense amplifier, with a reference voltage. The current sense amplifier is programmable in the CTRL register. When driving in PWM mode, the chopping current is calculated as follows:

$$I_{\text{CHOP}} = \frac{2.75\text{V} \cdot \text{TORQUE}}{256 \cdot \text{ISGAIN} \cdot R_{\text{SENSE}}} \quad (1)$$

Where TORQUE is the setting of the TORQUE bits, and ISGAIN is the programmed gain of the ISENSE amplifiers (5, 10, 20, or 40).

### 7.3.3 Microstepping Indexer

Built-in indexer logic in the DRV8711 allows a number of different stepping configurations. The MODE bits in the CTRL register are used to configure the stepping format as shown in [Table 3](#).

**Table 3. Microstepping Indexer Logic**

| MODE3 | MODE2 | MODE1 | MODE0 | STEP MODE                                       |
|-------|-------|-------|-------|-------------------------------------------------|
| 0     | 0     | 0     | 0     | Full-step (2-phase excitation) with 71% current |
| 0     | 0     | 0     | 1     | 1/2 step                                        |
| 0     | 0     | 1     | 0     | 1/4 step                                        |
| 0     | 0     | 1     | 1     | 1/8 step                                        |
| 0     | 1     | 0     | 0     | 1/16 step                                       |
| 0     | 1     | 0     | 1     | 1/32 step                                       |
| 0     | 1     | 1     | 0     | 1/64 step                                       |
| 0     | 1     | 1     | 1     | 1/128 step                                      |
| 1     | 0     | 0     | 0     | 1/256 step                                      |

Table 4 shows the relative current and step directions for full-step through 1/8-step operation. Higher microstepping resolutions follow the same pattern. The AOUT current is the sine of the electrical angle; BOUT current is the cosine of the electrical angle.

The reset state is 45°. This state is entered at power up or application of RESETn. This is shown in Table 4 by cells shaded in yellow.

**Table 4. Step Directions**

| FULL STEP | 1/2 STEP | 1/4 STEP | 1/8 STEP | AOUT CURRENT<br>(% FULL-SCALE) | BOUT CURRENT<br>(% FULL-SCALE) | ELECTRICAL<br>ANGLE<br>(DEGREES) |
|-----------|----------|----------|----------|--------------------------------|--------------------------------|----------------------------------|
|           | 1        | 1        | 1        | 0                              | 100                            | 0                                |
|           |          |          | 2        | 20                             | 98                             | 11.325                           |
|           |          | 2        | 3        | 38                             | 92                             | 22.5                             |
|           |          |          | 4        | 56                             | 83                             | 33.75                            |
| 1         | 2        | 3        | 5        | 71                             | 71                             | 45 (home state)                  |
|           |          |          | 6        | 83                             | 56                             | 56.25                            |
|           |          | 4        | 7        | 92                             | 38                             | 67.5                             |
|           |          |          | 8        | 98                             | 20                             | 78.75                            |
|           | 3        | 5        | 9        | 100                            | 0                              | 90                               |
|           |          |          | 10       | 98                             | –20                            | 101.25                           |
|           |          | 6        | 11       | 92                             | –38                            | 112.5                            |
|           |          |          | 12       | 83                             | –56                            | 123.75                           |
| 2         | 4        | 7        | 13       | 71                             | –71                            | 135                              |
|           |          |          | 14       | 56                             | –83                            | 146.25                           |
|           |          | 8        | 15       | 38                             | –92                            | 157.5                            |
|           |          |          | 16       | 20                             | –98                            | 168.75                           |
|           | 5        | 9        | 17       | 0                              | –100                           | 180                              |
|           |          |          | 18       | –20                            | –98                            | 191.25                           |
|           |          | 10       | 19       | –38                            | –92                            | 202.5                            |
|           |          |          | 20       | –56                            | –83                            | 213.75                           |
| 3         | 6        | 11       | 21       | –71                            | –71                            | 225                              |
|           |          |          | 22       | –83                            | –56                            | 236.25                           |
|           |          | 12       | 23       | –92                            | –38                            | 247.5                            |
|           |          |          | 24       | –98                            | –20                            | 258.75                           |
|           | 7        | 13       | 25       | –100                           | 0                              | 270                              |
|           |          |          | 26       | –98                            | 20                             | 281.25                           |
|           |          | 14       | 27       | –92                            | 38                             | 292.5                            |
|           |          |          | 28       | –83                            | 56                             | 303.75                           |
| 4         | 8        | 15       | 29       | –71                            | 71                             | 315                              |
|           |          |          | 30       | –56                            | 83                             | 326.25                           |
|           |          | 16       | 31       | –38                            | 92                             | 337.5                            |
|           |          |          | 32       | –20                            | 98                             | 348.75                           |

At each rising edge of the STEP input, or each time a 1 is written to the RSTEP bit in the CTRL register, the indexer travels to the next state in the table. The direction is shown with the DIR pin high and the RDIR bit in the CTRL register set to 0, or the DIR pin low and the RDIR bit set to 1. If the DIR pin is low with the RDIR bit 0, or the DIR pin is high with the RDIR bit 1, the sequence is reversed. Positive current is defined as xOUT1 = positive with respect to xOUT2.

If the step mode is changed while stepping, the indexer will advance to the next valid state for the new MODE setting at the rising edge of STEP.

### 7.3.4 Current Regulation

The current through the motor windings is regulated by an adjustable fixed-off-time PWM current regulation circuit. When an H-bridge is enabled, current rises through the winding at a rate dependent on the DC voltage and inductance of the winding and the magnitude of the back EMF present. Once the current hits the current chopping threshold, the bridge disables the current for a fixed period of time, which is programmable between 500 nS and 128  $\mu$ S by writing to the TOFF bits in the OFF register. After the off time expires, the bridge is re-enabled, starting another PWM cycle.

In stepping motors, current regulation is used to vary the current in the two windings in a sinusoidal fashion to provide smooth motion.

The PWM chopping current is set by a comparator which compares the voltage across a current sense resistor connected to the xISENx pins, multiplied by the gain of the current sense amplifier, with a reference voltage. The current sense amplifier is programmable in the CTRL register.

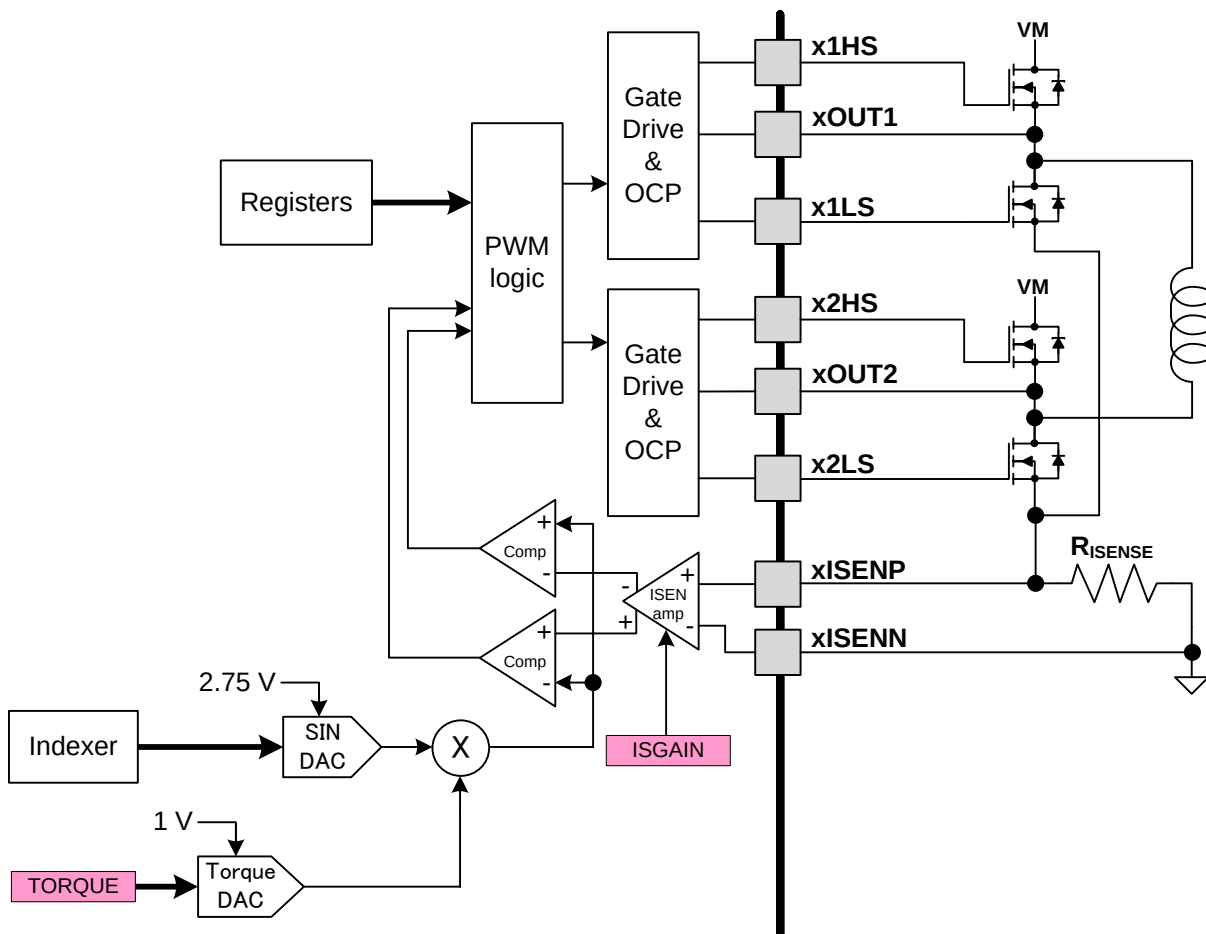


**Figure 8. PWM Chopping Current**

To generate the reference voltage for the current chopping comparator, the output of a sine lookup table is multiplied by the value of the bits in the TORQUE register. This result is applied to a sine-weighted DAC, whose full-scale output voltage is 2.75 V.

Therefore, the full-scale (100%) chopping current is calculated as follows:

$$I_{FS} = \frac{2.75V \bullet TORQUE}{256 \bullet ISGAIN \bullet R_{SENSE}}$$

where

- TORQUE is the setting of the TORQUE bits
- ISGAIN is the programmed gain of the ISENSE amplifiers (5, 10, 20, or 40)

Example:

If a 0.1-Ω sense resistor is used, ISGAIN is set to 0 (gain of 5), and TORQUE is set to 255, the full-scale (100%) chopping current will be  $(2.75\text{ V} \times 255) / (256 \times 5 \times 0.1\text{ }\Omega) = 5.5\text{ A}$ .

### 7.3.5 Decay Modes

During PWM current chopping, the H-bridge is enabled to drive through the motor winding until the PWM current chopping threshold is reached. This is shown in Figure 9, Item 1. The current flow direction shown indicates positive current flow in the step table below.

Once the chopping current threshold is reached, the H-bridge can operate in two different states, fast decay or slow decay.

In fast decay mode, once the PWM chopping current level has been reached, the H-bridge reverses state to allow winding current to flow in a reverse direction. The opposite FETs are turned on; as the winding current approaches zero, the bridge is disabled to prevent any reverse current flow. Fast decay mode is shown in Figure 9, item 2.

In slow decay mode, winding current is recirculated by enabling both of the low-side FETs in the bridge. This is shown in Figure 9, Item 3.

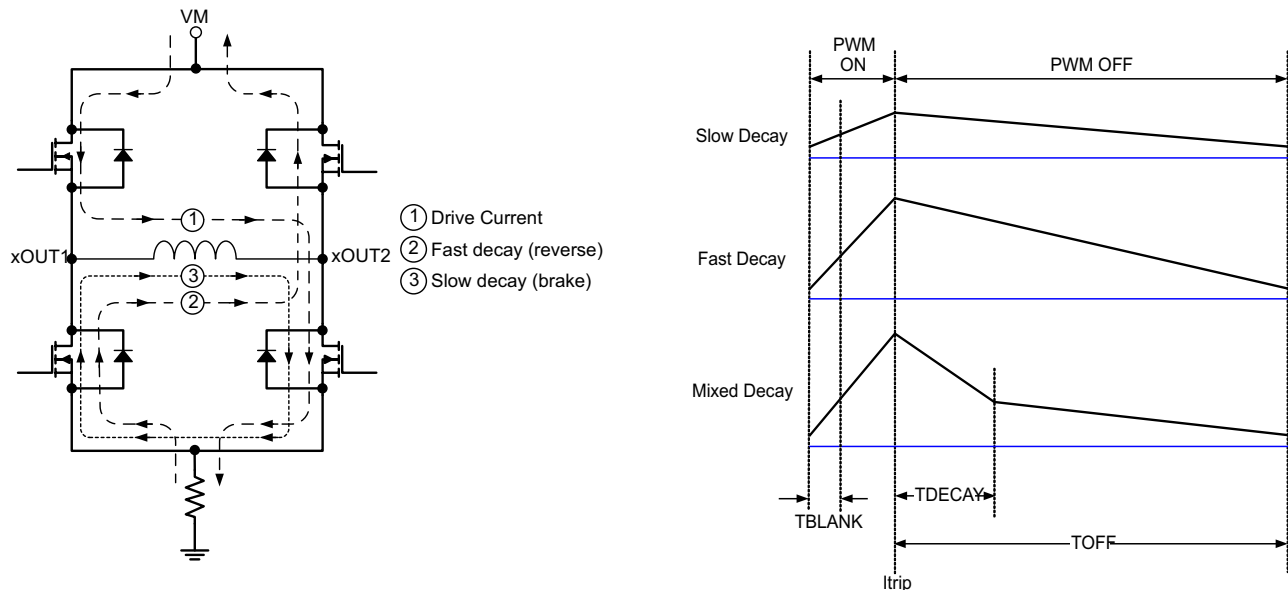


Figure 9. Decay Modes

The DRV8711 supports fast decay and slow decay modes in both indexer and direct PWM modes. In addition, in indexer mode only, it supports fixed mixed decay and auto-mixed decay modes. Decay mode is selected by the DECMOD bits in the DECAY register.

Mixed decay mode begins as fast decay, but after a programmable period of time (set by the TDECAY bits in the DECAY register) switches to slow decay mode for the remainder of the fixed off time. Even if mixed decay is selected, if the current is increasing or remaining the same (per the step table), then slow decay is used.

Auto-mixed decay mode samples the current level at the end of the blanking time, and if the current is above the  $I_{trip}$  threshold, immediately changes the H-bridge to fast decay. During fast decay, the (negative) current is monitored, and when it falls below the  $I_{trip}$  threshold (and another blanking time has passed), the bridge is switched to slow decay. Once the fixed off time expires, a new cycle is started.

If the bridge is turned on and at the end of  $TBLANK$  the current is below the  $I_{trip}$  threshold, the bridge remains on until the current reaches  $I_{trip}$ . Then slow decay is entered for the fixed off time, and a new cycle begins.

See [Figure 10](#) and [Figure 11](#).

The upper waveform shows the behavior if  $I < I_{trip}$  at the end of  $tBLANK$ . At slow motor speeds, where back EMF is not significant, the current increase during the ON phase is the same magnitude as the current decrease in fast decay, because both times are controlled by  $tBLANK$ , and the rate of change is the same (full  $V_M$  is applied to the load inductance in both cases, but in opposite directions). In this case, the current will gradually be driven down until the peak current is just hitting  $I_{trip}$  at the end of the blanking time, after which some cycles will be slow decay, and some will be mixed decay.

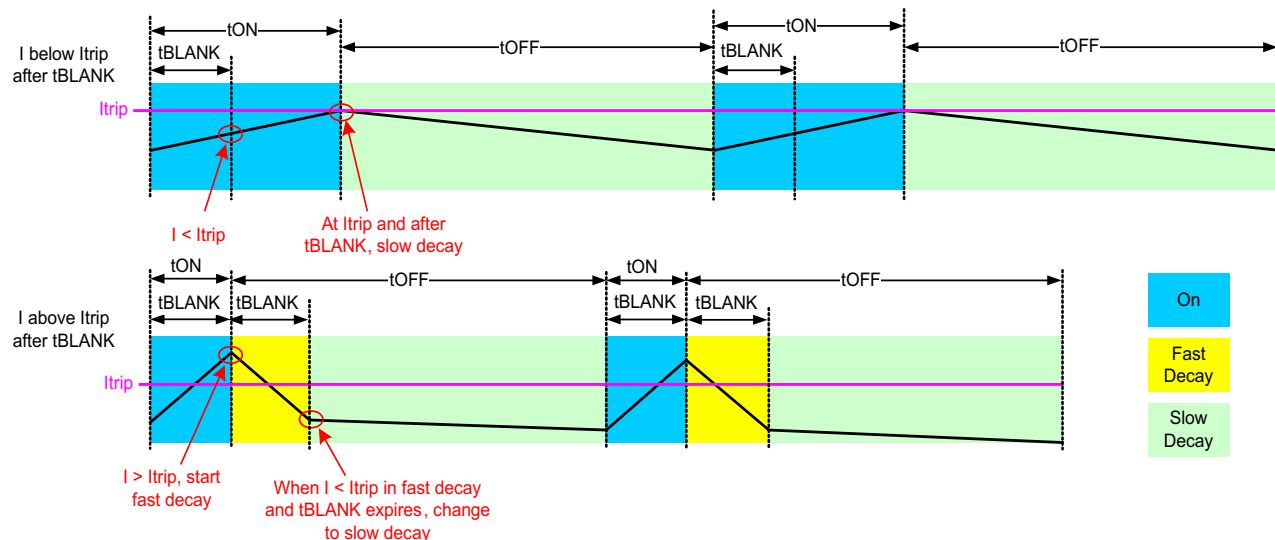


**Figure 10.  $I < I_{trip}$  at the End of  $tBLANK$**

If the  $I_{trip}$  level changes during a PWM cycle (in response to a step command to the indexer), the current cycle is immediately terminated, and a new cycle is begun. Refer to the drawing below.

If the  $I_{trip}$  level has increased, the H-bridge will immediately turn on; if the  $I_{trip}$  level has decreased, fast decay mode is begun immediately. The top waveform shows what happens when the  $I_{trip}$  threshold decreases during a PWM cycle. The lower  $I_{trip}$  level results in the current being above the  $I_{trip}$  threshold at the end of  $tBLANK$  on the following cycle. Fast decay is entered until the current is driven below the  $I_{trip}$  threshold.

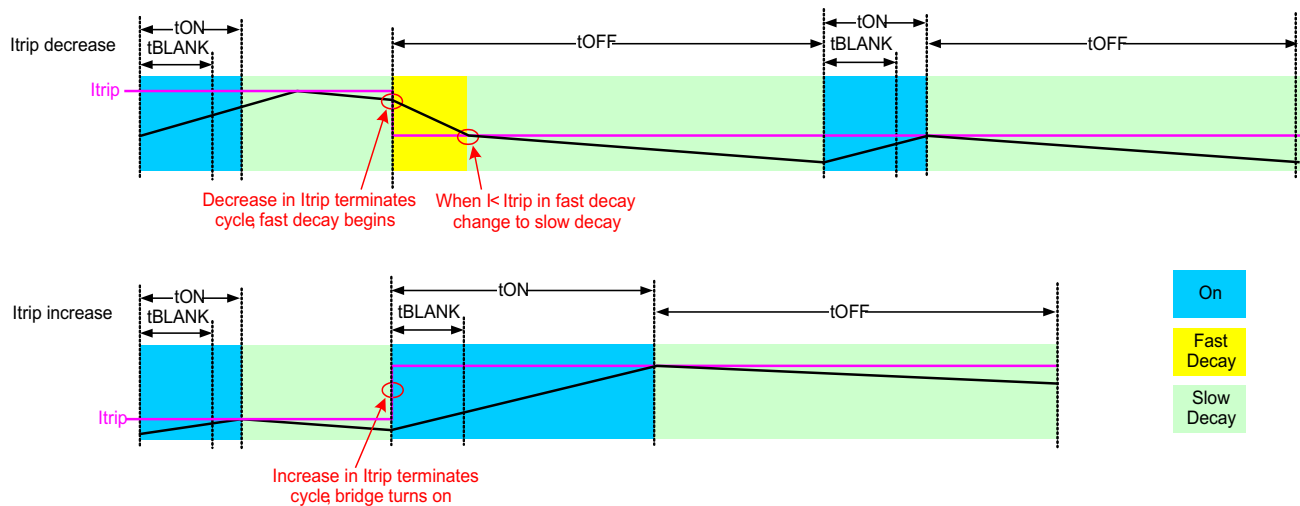


Figure 11. Itrip Level Changing During a PWM Cycle

To accurately detect zero current, an internal offset has been intentionally placed in the zero current detection circuit. If an external filter is placed on the current sense resistor to the xISENN and xISENP pins, symmetry must be maintained. This means that any resistance between the bottom of the  $R_{ISENSE}$  resistor and xISENN must be matched by the same resistor value (1% tolerance) between the top of the  $R_{ISENSE}$  resistor and xISENP. Ensure a maximum resistance of 500  $\Omega$ . The capacitor value should be chosen such that the RC time constant is between 50 ns and 60 ns. Any external filtering on these pins is optional and not required for operation.

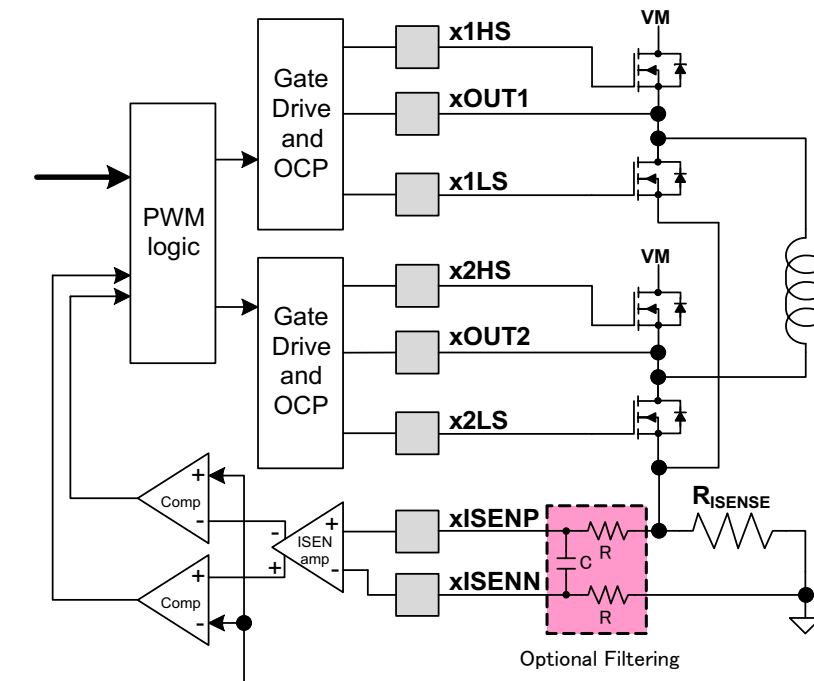


Figure 12. Optional Filtering Between  $R_{ISENSE}$  and xINSENx

### 7.3.6 Blanking Time

After the current is enabled in an H-bridge, the voltage on the ISEN pin is ignored for a period of time before enabling the current sense circuitry. This blanking time is adjustable from 1  $\mu$ s to 5.12  $\mu$ s, in 20 ns increments, by setting the TBLANK bits in the BLANK register. Note that the blanking time also sets the minimum on time of the PWM.

The same blanking time is applied to the fast decay period in auto decay mode. The PWM will ignore any transitions on *Itrip* after entering fast decay mode, until the blanking time has expired.

To provide better current control at very low current steps, an adaptive blanking time mode can be enabled by setting the ABT bit in the BLANK register. If ABT is set, at current levels below 30% of full scale current (as determined by the step table), the blanking time (so also the minimum on time) is cut in half, to 50% of the value programmed by the TBLANK bits.

For higher degrees of micro-stepping, TI recommends enabling ABT bit for better current regulation.

### 7.3.7 Predrivers

An internal charge pump circuit and predrivers inside the DRV8711 directly drive N-channel MOSFETs, which drive the motor current.

The peak drive current of the predrivers is adjustable by setting the bits in the DRIVE register. Peak source currents may be set to 50 mA, 100 mA, 150 mA, or 200 mA. The peak sink current is approximately 2x the peak source current. Adjusting the peak current will change the output slew rate, which also depends on the FET input capacitance and gate charge.

When changing the state of the output, the peak current is applied for a short period of time ( $t_{DRIVE}$ ), to charge the gate capacitance. After this time, a weak current source is used to keep the gate at the desired state. When selecting the gate drive strength for a given external FET, the selected current must be high enough to fully charge and discharge the gate during the time when driven at full current, or excessive power will be dissipated in the FET.

During high-side turnon, the low-side gate is pulled low. This prevents the gate-source capacitance of the low-side FET from inducing turnon.

The predriver circuits include enforcement of a dead time in analog circuitry, which prevents the high-side and low-side FETs from conducting at the same time. Additional dead time is added with digital delays. This delay can be selected by setting the DTIME bits in the CTRL register.

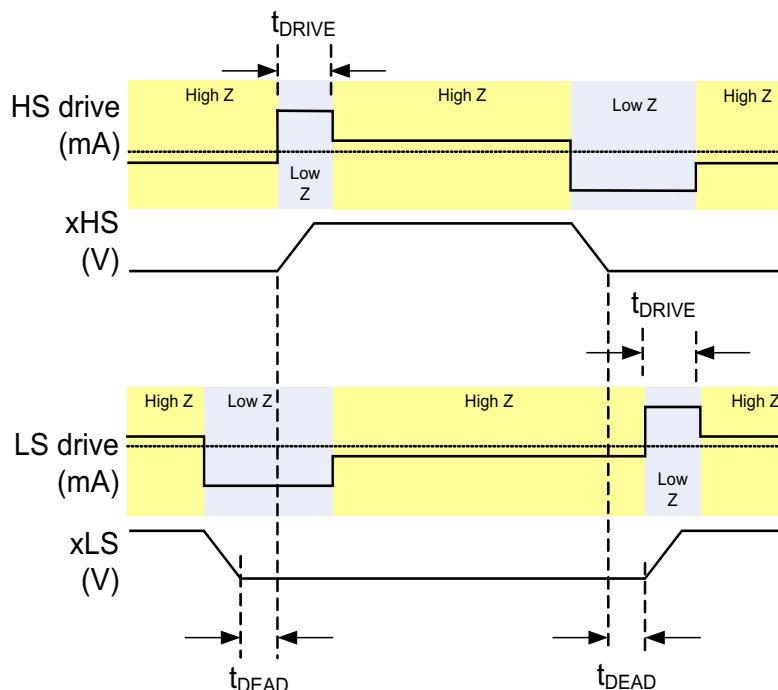
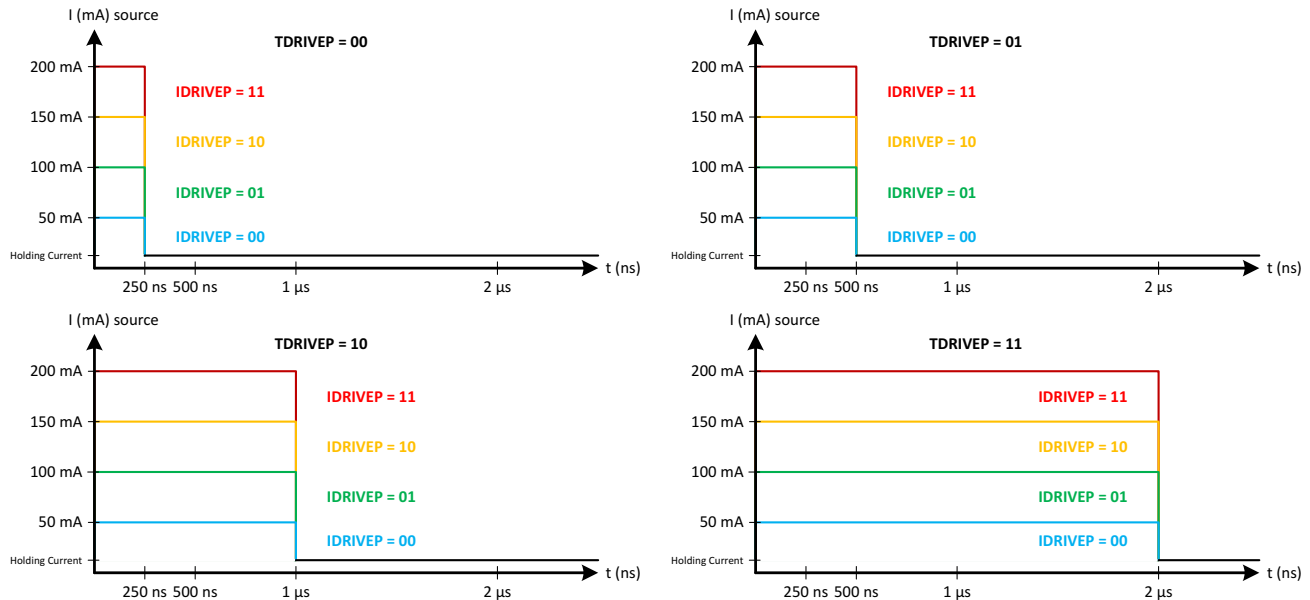


**Figure 13. Predrivers**

## Gate Pre-drive Source Capability



## Gate Pre-drive Sink Capability

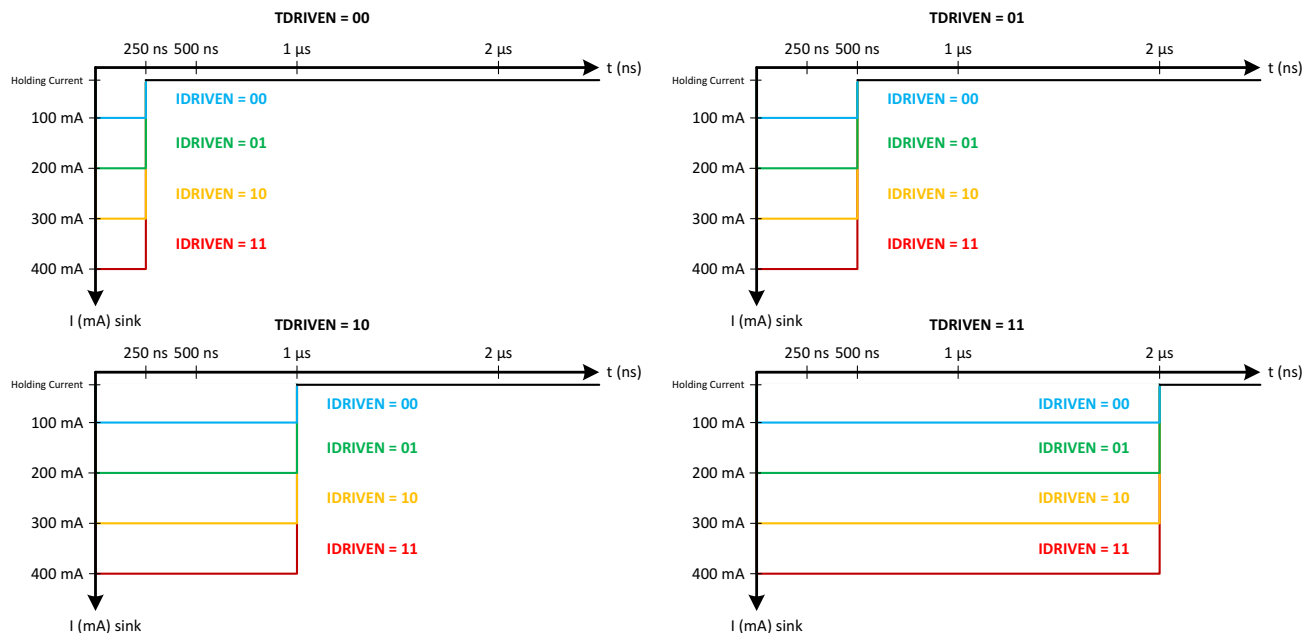


Figure 14. Gate Pre-Drive Source/Sink Capability

### 7.3.8 Configuring Predrivers

IDRIVE and TDRIVE are selected based on the size of external FETs used. These registers need to be configured so that the FET gates are charged completely during TDRIVE. If IDRIVE and TDRIVE are chosen to be too low for a given FET, then the FET may not turn on completely. TI suggests adjusting these values in-system with the required external FETs and stepper motor to determine the best possible setting for any application.

TDRIVE will not increase the PWM time or change the PWM chopping frequency.

In a system with capacitor charge  $Q$  and desired rise time  $RT$ , IDRIVE and TDRIVE can be initially selected based on:

$$\text{IDRIVE} > Q / RT$$

$$\text{TDRIVE} > 2 \times RT$$

For best results, select the smallest IDRIVE and TDRIVE that meet the above conditions.

Example:

If the gate charge is 15 nC and the desired rise time is 400 ns, then select:

$$\text{IDRIVEP} = 50 \text{ mA}, \text{IDRIVEN} = 100 \text{ mA}$$

$$\text{TDRIVEP} = \text{TDRIVEN} = 1 \mu\text{s}$$

### 7.3.9 External FET Selection

In a typical setup, the DRV8711 can support external FETs over 50 nC each. However, this capacity can be lower or higher based on the device operation. For an accurate calculation of FET driving capacity, use the following equation.

$$Q < \frac{20\text{mA} \cdot (2 \cdot \text{DTIME} + \text{TBLANK} + \text{TOFF})}{4} \quad (3)$$

Example:

If a DTIME is set to 0 (400 ns), TBLANK is set to 0 (1  $\mu\text{s}$ ), and TOFF is set to 0 (500 ns), then the DRV8711 will support  $Q < 11.5 \text{ nC}$  FETs (this is an absolute worst-case scenario with a PWM frequency approximately 430 kHz).

If a DTIME is set to 0 (400 ns), TBLANK is set to 0 (1  $\mu\text{s}$ ), and TOFF is set to 0x14 (10  $\mu\text{s}$ ), then the DRV8711 will support  $Q < 59 \text{ nC}$  FETs (PWM frequency approximately 85 kHz).

If a DTIME is set to 0 (400 ns), TBLANK is set to 0 (1  $\mu\text{s}$ ), and TOFF is set to 0x60 (48  $\mu\text{s}$ ), then the DRV8711 will support  $Q < 249 \text{ nC}$  FETs (PWM frequency approximately 20 kHz).

### 7.3.10 Stall Detection

The DRV8711 implements a back EMF monitoring scheme that is capable of detecting a stall during stepper motor motion. This stall detection is intended to be used to get an indication when a motor is run into a mechanical stop, or when an increased torque load on the motor causes it to stall.

To determine that a stall has occurred, a drop in motor back EMF is detected. The DRV8711 supports two methods of this detection: an automatic internal stall detection circuit, or the ability to use an external microcontroller to monitor back EMF.

During a zero-current step, one side of the H-bridge is placed in a high impedance state, and the opposite low-side FET is turned on for a brief duration defined by TORQUE register SMPLTH bit [10:8]. This allows the current to decay quickly through the low-side FET and the opposite body diode. Which side of the bridge is tri-state and which one is driven low depends on the current direction on the previous step. The bridge with the high side that has been actively PWMed (at the beginning of the PWM cycle during blank time) before entering the zero-current step will be held low and the opposite side will be tri-stated.

Back EMF is sampled on the tri-stated output pin at the end of SMPLTH time (TORQUE register bit [10:8]). The back EMF from the selected pin is divided by 4, 8, 16, or 32, depending on the setting of the VDIV bits in the STALL register. The voltage is buffered and held on an external capacitor placed on the BEMF pin. The signal on the BEMF output pin can be further processed by a microcontroller to implement more advanced control and stall detection algorithms.

The SMPLTH bit [10] is a write-only bit. When read, the bit always reads 0. TI recommends to maintain the value of the bit locally. When a change in the TORQUE register is desired, the bit can be read locally and added to the other bits to complete the value.

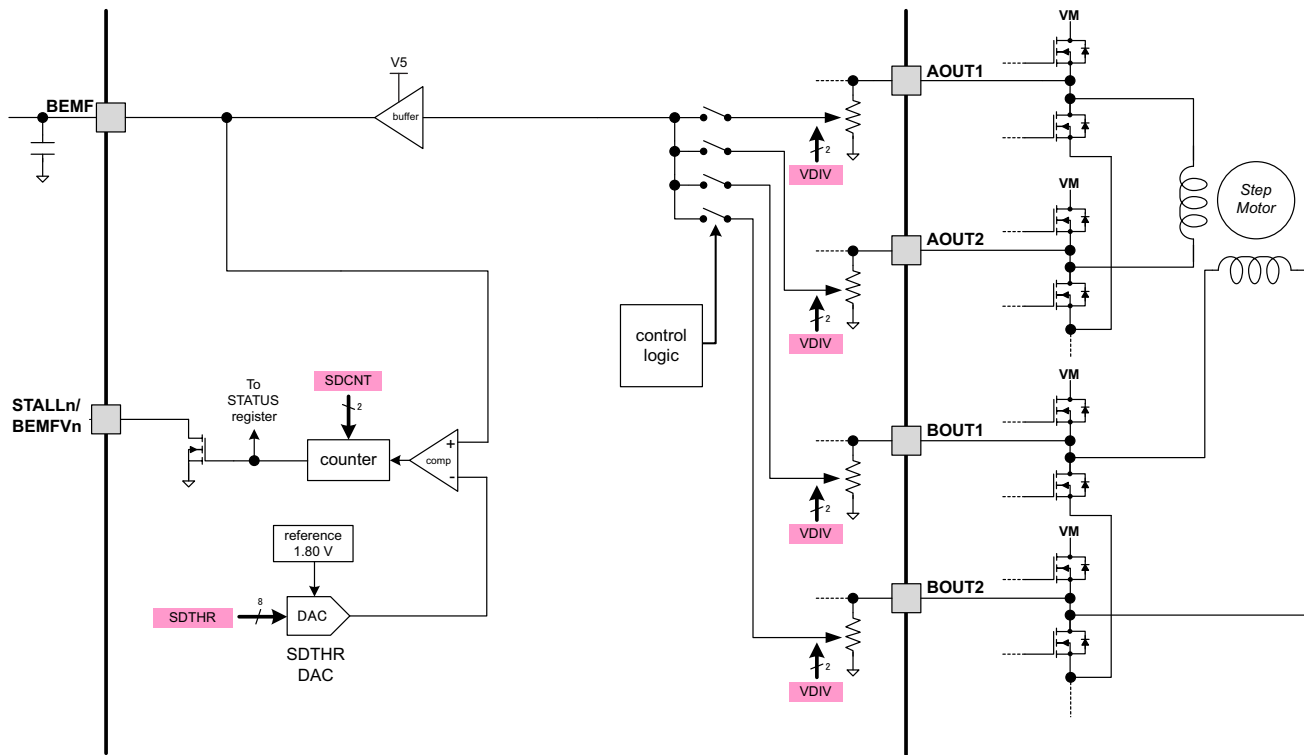


Figure 15. Stall Detection

### 7.3.10.1 Internal Stall Detection

To use internal stall detection, the EXSTALL bit in the CTRL register is set to 0. In this mode, the STALLn/BEMFVn output pin is used to signal a valid stall condition.

The time between step inputs must be greater than SMPLTH time for back EMF sampling.

Using internal stall detection, a stall is detected when the sampled back EMF drops below the value set by the SDTHR bits in the STALL register. A programmable counter circuit allows the assertion of the STALLn output to be delayed until the back EMF has been sampled below the SDTHR value for more than one zero-current step. The counter is programmed by the SDCNT bits in the STALL register, and provides selections of 1, 2, 4, or 8 steps.

When the stall is detected (at the end of a SMPLTH interval), the STALLn/BEMFVn pin is driven active low, and the STD bit and the STDLAT bit in the STATUS register are set. The STALLn/BEMFVn pin will deassert and the STD bit will automatically clear at the next zero-current step if a stall condition is not detected, while the STDLAT bit will remain set until a 0 is written to it. The STDLAT is reset when the STD bit clears after the first zero-cross step that does not detect a stall condition.

This stall detection scheme is only effective when the motor is stalled while running at or above some minimum speed. Because it relies on detecting a drop in motor back EMF, the motor must be rotating with sufficient speed to generate a detectable back EMF. During motor start-up, and at very slow step rates, the stall detection is not reliable.

Because back EMF can only be sampled during a zero-current state, stall detection is not possible in full step mode. During full-step operation, the stall detect circuit is gated off to prevent false signaling of a stall.

The correct setting of the SDTHR bits needs to be determined experimentally. It is dependent on many factors, including the electrical and mechanical characteristics of the load, the peak current setting, and the supply voltage.

### **7.3.10.2 External Stall Detection**

To use an external microcontroller to manage stall detection, the EXSTALL bit in the CTRL register is set to 1. In this mode, the STALLn / BEMFVn output pin is used to signal a valid back EMF measurement is ready. In addition, the SDT and SDTLAT bits are also set at this time.

BEMFVn and BEMF are still valid outputs in this mode even if the step time is smaller than SMPLTH time.

When the BEMFVn pin goes active low, it is an indication that a valid back EMF voltage measurement is available. This signal could be used, for example, to trigger an interrupt on a microcontroller. The microcontroller can then sample the voltage present (using an A/D converter) on the BEMF pin.

After sampling the back EMF voltage, the microcontroller writes a 0 to the SDTLAT bit to clear the SDT bit and BEMFVn pin, in preparation for the next back EMF sample. If the SDTLAT bit is not cleared by the microcontroller, it will automatically be cleared in the next zero-current step.

For either internal or external stall detection, at very high motor speeds when the PWM duty cycle approaches 100%, the inductance of the motor and the short duration of each step may cause the time required for current recirculation to exceed the step time. In this case, back EMF will not be correctly sampled, and stall detection cannot function. This condition occurs most at high degrees of micro-stepping, because the zero current step lasts for a shorter duration. It is advisable to run the motor at lower degrees of micro-stepping at higher speeds to allow time for current recirculation if stall detection is needed in this condition.

### **7.3.11 Protection Circuits**

The DRV8711 is fully protected against undervoltage, overcurrent and overtemperature events.

#### **7.3.11.1 Overcurrent Protection (OCP)**

Overcurrent is sensed by monitoring the voltage drop across the external FETs. If the voltage across a driven FET exceeds the value programmed by the OCPH bits in the DRIVE register for more than the time period specified by the OCPDEG bits in the DRIVE register, an OCP event is recognized. When operating in direct PWM mode, during an OCP event, the H-bridge experiencing the OCP event is disabled; if operating in indexer mode, both H-bridges will be disabled. In addition, the corresponding xOCP bit in the STATUS register is set, and the FAULTn pin is driven low. The H-bridge(s) will remain off, and the xOCP bit will remain set, until it is written to 0, or the device is reset.

#### **7.3.11.2 Predriver Fault**

In PWM mode, if excessive current is detected on the gate drive outputs (which would be indicative of a failed/shorted output FET or PCB fault), the H-bridge experiencing the fault is disabled, the xPDF bit in the STATUS register is set, and the FAULTn pin is driven low. The H-bridge will remain off, and the xPDF bit will remain set until it is written to 0 or the device is reset.

When in indexer mode, both H-bridges are disabled, the xPDF bit in the STATUS register is set, and the FAULTn pin is driven low. The H-bridges will remain off, and the xPDF bit will remain set until it is written to 0 or the device is reset.

#### **7.3.11.3 Thermal Shutdown (TSD)**

If the die temperature exceeds safe limits, all FETs in the H-bridge will be disabled, the OTS bit in the STATUS register will be set, and the FAULTn pin will be driven low. Once the die temperature has fallen to a safe level operation will automatically resume and the OTS bit will reset. The FAULTn pin will be released after operation has resumed.

#### **7.3.11.4 Undervoltage Lockout (UVLO)**

If at any time the voltage on the VM pin falls below the undervoltage lockout threshold voltage, all FETs in the H-bridge will be disabled, the UVLO bit in the STATUS register will be set, and the FAULTn pin will be driven low. Operation will resume when VM rises above the UVLO threshold. The UVLO bit will remain set until it is written to 0. The FAULTn pin will be released after operation has resumed.

During any of these fault conditions, the STEP input pin will be ignored.

## 7.4 Device Functional Modes

### 7.4.1 RESET and SLEEPn Operation

An internal power-up reset circuit monitors the voltage applied to the VM pin. If VM falls below the VM undervoltage lockout voltage, the part is reset, as described below for the case of asserting the RESET pin.

If the RESET pin is asserted, all internal logic including the indexer is reset. All registers are returned to their initial default conditions. The power stage will be disabled, and all inputs, including STEP and the serial interface, are ignored when RESET is active.

On exiting reset state, some time (approximately 1 mS) needs to pass before the part is fully functional.

Applying an active low input to the SLEEPn input pin will place the device into a low power state. In sleep mode, the motor driver circuitry is disabled, the gate drive regulator and charge pump are disabled, and all analog circuitry is placed into a low power state. The digital circuitry in the device still operates, so the device registers can still be accessed via the serial interface.

When SLEEPn is active, the RESET pin does not function. SLEEPn must be exited before RESET will take effect. SLEEPn must also be exited to clear the UVLO bit in the status register.

When exiting from sleep mode, some time (approximately 1 mS) needs to pass before applying a STEP input, to allow the internal circuitry to stabilize.

### 7.4.2 Microstepping Drive Current

Figure 16 shows examples of stepper motor current in one of the windings. Because these waveforms are dependent on DRV8711 register settings as well as the external FETs, sense resistor, and stepper motor, they should only be used as a reference.

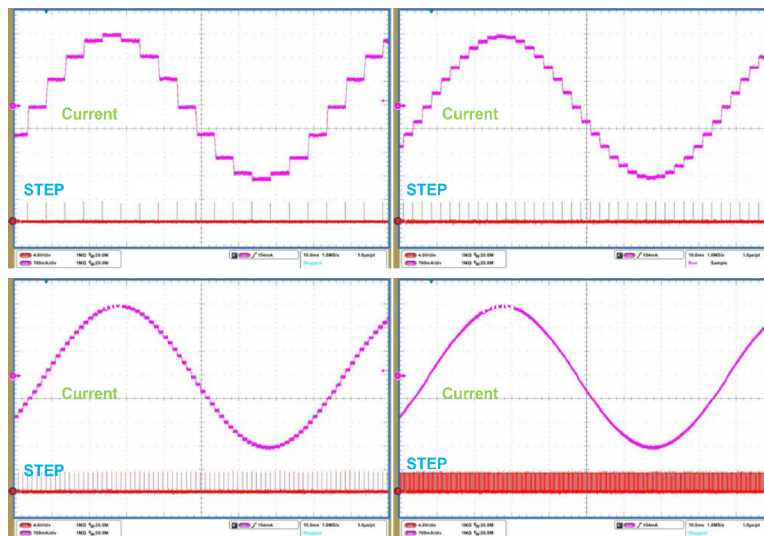


**Figure 16. Microstepping Drive Current**

## 7.5 Programming

### 7.5.1 Serial Data Format

The serial data consists of a 16-bit serial write, with a read/write bit, 3 address bits and 12 data bits. The 3 address bits identify one of the registers defined in the register section above. To complete the read or write transaction, SCS must be set to a logic 0.

To write to a register, data is shifted in after the address as shown in the timing diagram below. The first bit at the beginning of the access must be logic low for a write operation.

## Programming (continued)

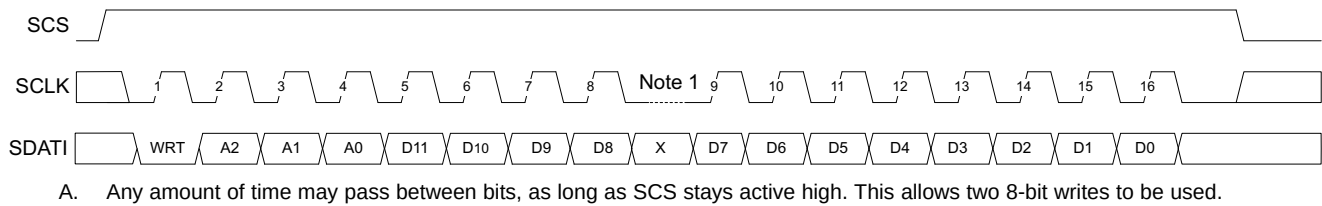


**Figure 17. Write Operation**

Data may be read from the registers through the SDATO pin. During a read operation, only the address is used from the SDATI pin; the data bits following are ignored. The first bit at the beginning of the access must be logic high for a read operation.

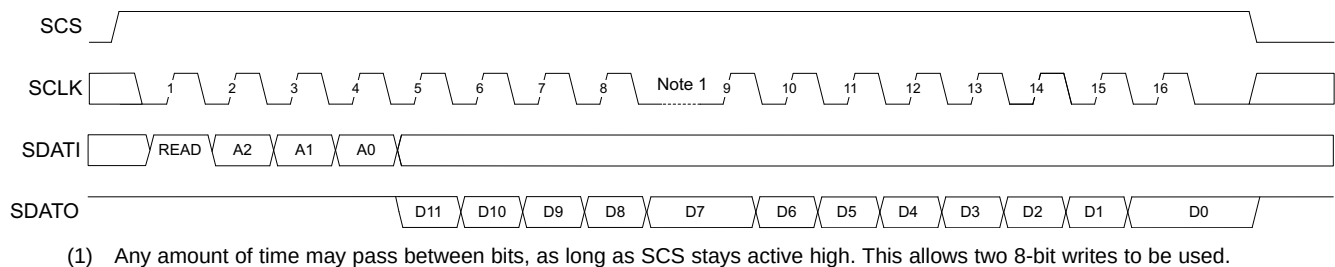


**Figure 18. Read Operation**

## 7.6 Register Maps

### 7.6.1 Control Registers

The DRV8711 uses internal registers to control the operation of the motor. The registers are programmed through a serial SPI communications interface. At power up or reset, the registers will be preloaded with default values as shown in [CTRL Register \(Address = 0x00\)](#) to [STATUS Register \(Address = 0x07\)](#).

[Figure 19](#) is a map of the DRV8711 registers.

Individual register contents are defined in [CTRL Register \(Address = 0x00\)](#) to [STATUS Register \(Address = 0x07\)](#).

| DRV8711 REGISTER MAP |          |         |         |          |         |      |         |      |        |       |      |      |    |             |
|----------------------|----------|---------|---------|----------|---------|------|---------|------|--------|-------|------|------|----|-------------|
| Name                 | 11       | 10      | 9       | 8        | 7       | 6    | 5       | 4    | 3      | 2     | 1    | 0    |    | Address Hex |
| CTRL                 | DTIME    |         | ISGAIN  |          | EXSTALL | MODE |         |      |        | RSTEP | RDIR | ENBL | RW | 00          |
| TORQUE               | Reserved | SMP LTH |         |          | TORQUE  |      |         |      |        |       |      |      | RW | 01          |
| OFF                  | Reserved |         |         | PWM MODE | TOFF    |      |         |      |        |       |      |      | RW | 02          |
| BLANK                | Reserved |         |         | ABT      | TBLANK  |      |         |      |        |       |      |      | RW | 03          |
| DECAY                | Reserved | DECMOD  |         |          | TDECAY  |      |         |      |        |       |      |      | RW | 04          |
| STALL                | VDIV     |         | SDCNT   |          | SDTHR   |      |         |      |        |       |      |      | RW | 05          |
| DRIVE                | IDRIVEP  |         | IDRIVEN |          | TDRIVEP |      | TDRIVEN |      | OCPDEG |       | OCPH |      | RW | 06          |
| STATUS               | Reserved |         |         |          | STDLAT  | STD  | UVLO    | BPDF | APDF   | BOCP  | AOCP | OTS  | RW | 07          |
| Name                 | 11       | 10      | 9       | 8        | 7       | 6    | 5       | 4    | 3      | 2     | 1    | 0    |    | Address Hex |

**Figure 19. DRV8711 Register Map**

## Register Maps (continued)

### 7.6.2 CTRL Register (Address = 0x00)

| BIT   | NAME    | SIZE | R/W | DEFAULT | DESCRIPTION                                                                                                                                                                                                          |
|-------|---------|------|-----|---------|----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| 0     | ENBL    | 1    | R/W | 0       | <b>0: Disable motor</b><br>1: Enable motor                                                                                                                                                                           |
| 1     | RDIR    | 1    | R/W | 0       | <b>0: Direction set by DIR pin</b><br>1: Direction set by inverse of DIR pin                                                                                                                                         |
| 2     | RSTEP   | 1    | W   | 0       | 0: No action<br>1: Indexer will advance one step; automatically cleared after write                                                                                                                                  |
| 6-3   | MODE    | 4    | R/W | 0010    | 0000: Full-step, 71% current<br>0001: Half step<br><b>0010: 1/4 step</b><br>0011: 1/8 step<br>0100: 1/16 step<br>0101: 1/32 step<br>0110: 1/64 step<br>0111: 1/128 step<br>1000: 1/256 step<br>1001 – 1111: Reserved |
| 7     | EXSTALL | 1    | R/W | 0       | <b>0: Internal stall detect</b><br>1: External stall detect                                                                                                                                                          |
| 9-8   | ISGAIN  | 2    | R/W | 00      | ISENSE amplifier gain set<br><b>00: Gain of 5</b><br>01: Gain of 10<br>10: Gain of 20<br>11: Gain of 40                                                                                                              |
| 11-10 | DTIME   | 2    | R/W | 11      | Dead time set<br>00: 400 ns dead time<br>01: 450 ns dead time<br>10: 650 ns dead time<br><b>11: 850 ns dead time</b>                                                                                                 |

### 7.6.3 TORQUE Register (Address = 0x01)

| BIT  | NAME                  | SIZE | R/W | DEFAULT | DESCRIPTION                                                                                                                                                                                                |
|------|-----------------------|------|-----|---------|------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| 7-0  | TORQUE                | 8    | R/W | 0xFF    | Sets full-scale output current for both H-bridges                                                                                                                                                          |
| 10-8 | SMPLTH <sup>(1)</sup> | 3    | R/W | 001     | Back EMF sample threshold<br>000: 50 $\mu$ s<br><b>001: 100 <math>\mu</math>s</b><br>010: 200 $\mu$ s<br>011: 300 $\mu$ s<br>100: 400 $\mu$ s<br>101: 600 $\mu$ s<br>110: 800 $\mu$ s<br>111: 1000 $\mu$ s |
| 11   | Reserved              | 1    | -   | -       | Reserved                                                                                                                                                                                                   |

(1) Bit 10 is a write only bit. When read, bit 10 will always return 0.

### 7.6.4 OFF Register (Address = 0x02)

| BIT  | NAME     | SIZE | R/W | DEFAULT | DESCRIPTION                                                                             |
|------|----------|------|-----|---------|-----------------------------------------------------------------------------------------|
| 7-0  | TOFF     | 8    | R/W | 0x30    | Sets fixed off time, in increments of 500 ns<br>0x00: 500 ns<br>0xFF: 128 $\mu$ s       |
| 8    | PWMODE   | 1    | R/W | 0       | <b>0: Use internal indexer</b><br>1: Bypass indexer, use xINx inputs to control outputs |
| 11-9 | Reserved | 3    | -   | -       | Reserved                                                                                |

### 7.6.5 BLANK Register (Address = 0x03)

| BIT  | NAME     | SIZE | R/W | DEFAULT | DESCRIPTION                                                                                                                                                                                                       |
|------|----------|------|-----|---------|-------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| 7-0  | TBLANK   | 8    | R/W | 0x80    | Sets current trip blanking time, in increments of 20 ns<br>0x00: 1 $\mu$ s<br>...<br>0x32: 1 $\mu$ s<br>0x33: 1.02 $\mu$ s<br>...<br>0xFE: 5.10 $\mu$ s<br>0xFF: 5.12 $\mu$ s<br>Also sets minimum on-time of PWM |
| 8    | ABT      | 1    | R/W | 0       | <b>0: Disable adaptive blanking time</b><br>1: Enable adaptive blanking time                                                                                                                                      |
| 11-9 | Reserved | 3    | -   | -       | Reserved                                                                                                                                                                                                          |

### 7.6.6 DECAY Register (Address = 0x04)

| BIT  | NAME     | SIZE | R/W | DEFAULT | DESCRIPTION                                                                                                                                                                                                                                                                                                                                                                                    |
|------|----------|------|-----|---------|------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| 7-0  | TDECAY   | 8    | R/W | 0x10    | Sets mixed decay transition time, in increments of 500 ns                                                                                                                                                                                                                                                                                                                                      |
| 10-8 | DECMOD   | 3    | R/W | 001     | 000: Force slow decay at all times<br><b>001: Slow decay for increasing current, mixed decay for decreasing current (indexer mode only)</b><br>010: Force fast decay at all times<br>011: Use mixed decay at all times<br>100: Slow decay for increasing current, auto mixed decay for decreasing current (indexer mode only)<br>101: Use auto mixed decay at all times<br>110 – 111: Reserved |
| 11   | Reserved | 1    | -   | -       | Reserved                                                                                                                                                                                                                                                                                                                                                                                       |

### 7.6.7 STALL Register (Address = 0x05)

| BIT   | NAME  | SIZE | R/W | DEFAULT | DESCRIPTION                                                                                                                                                                       |
|-------|-------|------|-----|---------|-----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| 7-0   | SDTHR | 8    | R/W | 0x40    | Sets stall detect threshold<br>The correct setting needs to be determined experimentally                                                                                          |
| 9-8   | SDCNT | 2    | R/W | 00      | <b>00: STALLn asserted on first step with back EMF below SDTHR</b><br>01: STALLn asserted after 2 steps<br>10: STALLn asserted after 4 steps<br>11: STALLn asserted after 8 steps |
| 11-10 | VDIV  | 2    | R/W | 00      | <b>00: Back EMF is divided by 32</b><br>01: Back EMF is divided by 16<br>10: Back EMF is divided by 8<br>11: Back EMF is divided by 4                                             |

### 7.6.8 DRIVE Register (Address = 0x06)

| BIT | NAME    | SIZE | R/W | DEFAULT | DESCRIPTION                                                                                            |
|-----|---------|------|-----|---------|--------------------------------------------------------------------------------------------------------|
| 1-0 | OCPH    | 2    | R/W | 01      | OCP threshold<br>00: 250 mV<br><b>01: 500 mV</b><br>10: 750 mV<br>11: 1000 mV                          |
| 3-2 | OCPDEG  | 2    | R/W | 10      | OCP deglitch time<br>00: 1 $\mu$ s<br>01: 2 $\mu$ s<br><b>10: 4 <math>\mu</math>s</b><br>11: 8 $\mu$ s |
| 5-4 | TDRIVEN | 2    | R/W | 01      | Low-side gate drive time<br>00: 250 ns<br><b>01: 500 ns</b><br>10: 1 $\mu$ s<br>11: 2 $\mu$ s          |

| BIT   | NAME    | SIZE | R/W | DEFAULT | DESCRIPTION                                                                                                                                             |
|-------|---------|------|-----|---------|---------------------------------------------------------------------------------------------------------------------------------------------------------|
| 7-6   | TDRIVEP | 2    | R/W | 01      | High-side gate drive time<br>00: 250 ns<br><b>01: 500 ns</b><br>10: 1 $\mu$ s<br>11: 2 $\mu$ s                                                          |
| 9-8   | IDRIVEN | 2    | R/W | 10      | Low-side gate drive peak current<br>00: 100 mA peak (sink)<br>01: 200 mA peak (sink)<br><b>10: 300 mA peak (sink)</b><br>11: 400 mA peak (sink)         |
| 11-10 | IDRIVEP | 2    | R/W | 10      | High-side gate drive peak current<br>00: 50 mA peak (source)<br>01: 100 mA peak (source)<br><b>10: 150 mA peak (source)</b><br>11: 200 mA peak (source) |

### 7.6.9 STATUS Register (Address = 0x07)

| BIT  | NAME     | SIZE | R/W | DEFAULT | DESCRIPTION                                                                                                                                                                                                      |
|------|----------|------|-----|---------|------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| 0    | OTS      | 1    | R/W | 0       | 0: Normal operation<br>1: Device has entered overtemperature shutdown<br>Write a 0 to this bit to clear the fault.<br>Operation automatically resumes when the temperature has fallen to safe levels.            |
| 1    | AOCP     | 1    | R/W | 0       | 0: Normal operation<br>1: Channel A overcurrent shutdown<br>Write a 0 to this bit to clear the fault and resume operation                                                                                        |
| 2    | BOCP     | 1    | R/W | 0       | 0: Normal operation<br>1: Channel B overcurrent shutdown<br>Write a 0 to this bit to clear the fault and resume operation                                                                                        |
| 3    | APDF     | 1    | R/W | 0       | 0: Normal operation<br>1: Channel A predriver fault<br>Write a 0 to this bit to clear the fault and resume operation.                                                                                            |
| 4    | BPDF     | 1    | R/W | 0       | 0: Normal operation<br>1: Channel B predriver fault<br>Write a 0 to this bit to clear the fault and resume operation                                                                                             |
| 5    | UVLO     | 1    | R/W | 0       | 0: Normal operation<br>1: Undervoltage lockout<br>Write a 0 to this bit to clear the fault. The UVLO bit cannot be cleared in sleep mode. Operation automatically resumes when VM has increased above $V_{UVLO}$ |
| 6    | STD      | 1    | R   | 0       | 0: Normal operation<br>1: Stall detected                                                                                                                                                                         |
| 7    | STDLAT   | 1    | R/W | 0       | 0: Normal operation<br>1: Latched stall detect<br>Write a 0 to this bit to clear the fault and resume operation                                                                                                  |
| 11-8 | Reserved | 4    | -   | -       | Reserved                                                                                                                                                                                                         |

## 8 Application and Implementation

### NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

### 8.1 Application Information

The DRV8711 is used in bipolar stepper control. The microstepping motor predriver provides additional precision and a smooth rotation from the stepper motor.

#### 8.1.1 Sense Resistor

For optimal performance, it is important for the sense resistor to be:

- Surface-mount
- Low inductance
- Rated for high enough power
- Placed closely to the motor driver

The power dissipated by the sense resistor equals  $I_{\text{RMS}}^2 \times R$ . For example, if peak motor current is 3 A, RMS motor current is 2 A, and a 0.05-Ω sense resistor is used, the resistor will dissipate  $2 \text{ A}^2 \times 0.05 \text{ } \Omega = 0.2 \text{ W}$ . The power quickly increases with higher current levels.

Resistors typically have a rated power within some ambient temperature range, along with a derated power curve for high ambient temperatures. When a PCB is shared with other components generating heat, margin should be added. It is always best to measure the actual sense resistor temperature in a final system, along with the power MOSFETs, as those are often the hottest components.

Because power resistors are larger and more expensive than standard resistors, it is common practice to use multiple standard resistors in parallel, between the sense node and ground. This distributes the current and heat dissipation.

#### 8.1.2 Optional Series Gate Resistor

In high current or high voltage applications, the low side predriver fault may assert due to noise in the system. In this application, TI recommends placing a 47 to 120-Ω resistor in series with the low side output and the gate of the low side FET. TI also recommends setting the dead time to 850 ns when adding a series resistor.

### 8.2 Typical Application

The following design is a common application of the DRV8711.

## Typical Application (continued)

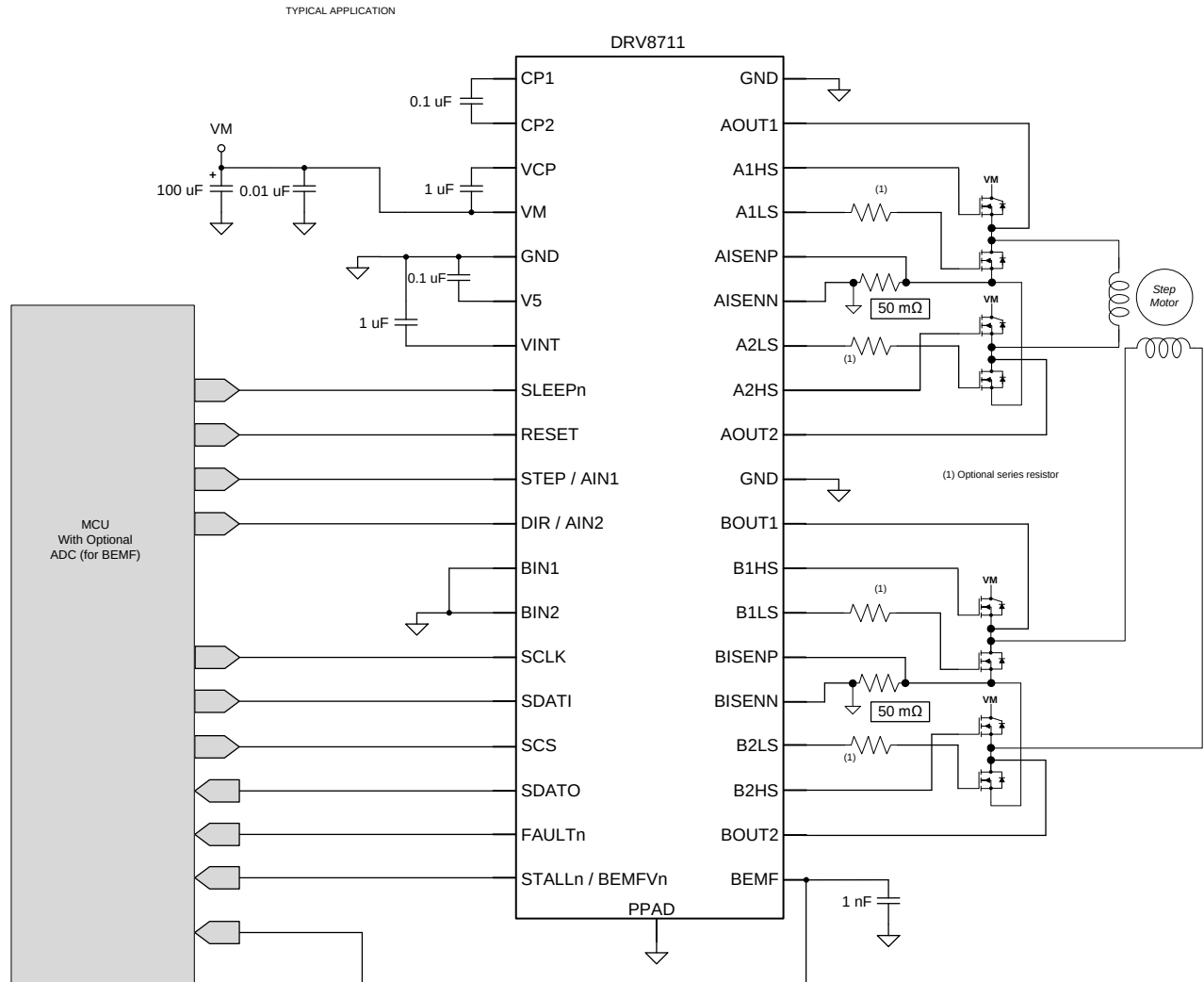


**Figure 20. Typical Application Schematic**

### 8.2.1 Design Requirements

For this design example, use the parameters listed in [Table 5](#) as the input parameters.

**Table 5. Design Parameters**

| DESIGN PARAMETER           | REFERENCE              | EXAMPLE VALUE          |
|----------------------------|------------------------|------------------------|
| Supply Voltage             | VM                     | 24 V                   |
| Motor Winding Resistance   | $R_L$                  | 3.9 $\Omega$           |
| Motor Winding Inductance   | $L_L$                  | 2.9 mH                 |
| Motor Full Step Angle      | $\theta_{\text{step}}$ | 1.8°/step              |
| Target Microstepping Level | $n_m$                  | 8 $\mu$ steps per step |
| Target Motor Speed         | v                      | 120 RPM                |
| Target Full-Scale Current  | $I_{FS}$               | 1.25 A                 |

## 8.2.2 Detailed Design Procedure

### 8.2.2.1 Stepper Motor Speed

The first step in configuring the DRV8711 requires the desired motor speed and microstepping level. If the target application requires a constant speed, then a square wave with frequency  $f_{\text{step}}$  must be applied to the STEP pin.

If the target motor start-up speed is too high, the motor will not spin. Make sure that the motor can support the target speed or implement an acceleration profile to bring the motor up to speed.

For a desired motor speed ( $V$ ), microstepping level ( $n_m$ ), and motor full step angle ( $\theta_{\text{step}}$ ),

$$f_{\text{step}} (\mu\text{steps/second}) = \frac{V \left( \frac{\text{rotations}}{\text{minute}} \right) \times 360 \left( \frac{^\circ}{\text{rotation}} \right) \times n_m \left( \frac{\mu\text{steps}}{\text{step}} \right)}{60 \left( \frac{\text{seconds}}{\text{minute}} \right) \times \theta_{\text{step}} \left( \frac{^\circ}{\text{step}} \right)} \quad (4)$$

$$f_{\text{step}} (\mu\text{steps/second}) = \frac{120 \left( \frac{\text{rotations}}{\text{minute}} \right) \times 360 \left( \frac{^\circ}{\text{rotation}} \right) \times 8 \left( \frac{\mu\text{steps}}{\text{step}} \right)}{60 \left( \frac{\text{seconds}}{\text{minute}} \right) \times 1.8 \left( \frac{^\circ}{\text{step}} \right)} \quad (5)$$

$\theta_{\text{step}}$  can be found in the stepper motor data sheet or written on the motor itself.

For the DRV8711, the microstepping level is set by the MODE bits in the CTRL register. Higher microstepping will mean a smoother motor motion and less audible noise, but will increase switching losses and require a higher  $f_{\text{step}}$  to achieve the same motor speed.

### 8.2.2.2 Current Regulation

In a stepper motor, the set full-scale current ( $I_{\text{FS}}$ ) is the maximum current driven through either winding. For the DRV8711, this quantity will depend on the analog voltage, the programmed torque and gain values, and the sense resistor value ( $R_{\text{SENSE}}$ ). During stepping, IFS defines the current chopping threshold ( $I_{\text{TRIP}}$ ) for the maximum current step. The gain of DRV8711 is set for 5 V/V.

$$I_{\text{FS}} (\text{A}) = \frac{2.75 (\text{V}) \times \text{TORQUE}}{256 \times \text{ISGAIN} \times R_{\text{SENSE}} (\Omega)} \quad (6)$$

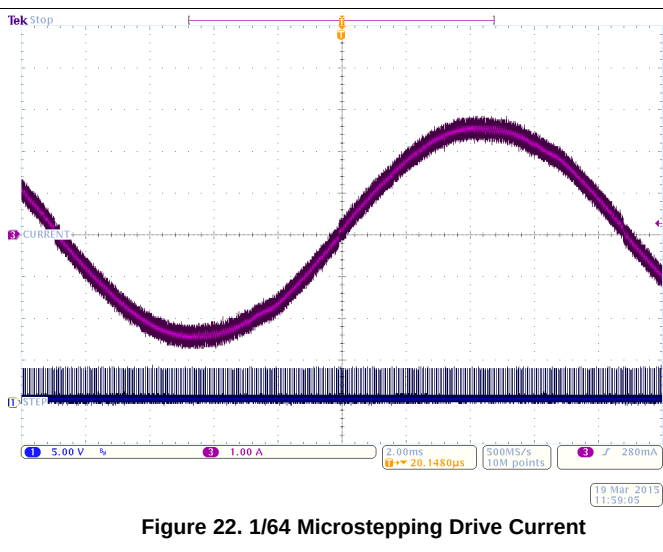
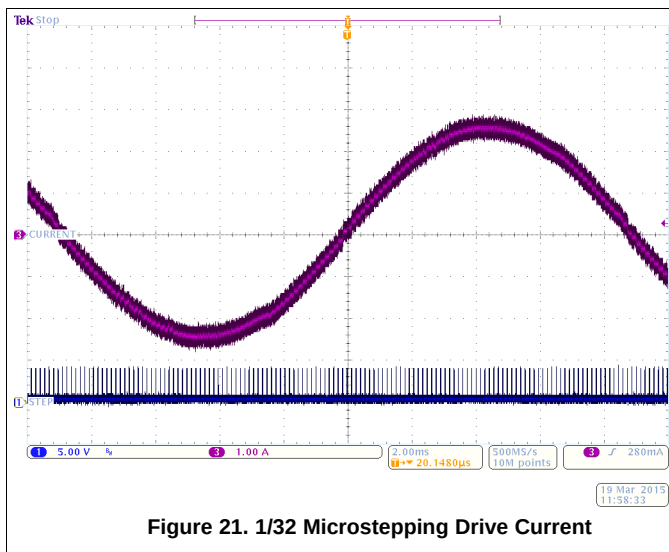
To achieve  $I_{\text{FS}} = 1.25 \text{ A}$  with  $R_{\text{SENSE}}$  of  $0.2 \Omega$  with a gain of 5, TORQUE should be set to 116(dec).

### 8.2.2.3 Decay Modes

The DRV8711 supports three different decay modes: slow decay, fast decay, and mixed decay. The DRV8711 also supports automatic mixed decay mode, which minimizes current ripple. The current through the motor windings is regulated using programmable settings for blanking, decay and off time. This means that after any drive phase, when a motor winding current has hit the current chopping threshold ( $I_{\text{TRIP}}$ ), the DRV8711 will place the winding in the programmed decay modes until the cycle has expired. Afterward, a new drive phase starts.

The blanking time  $T_{\text{BLANK}}$  defines the minimum drive time for the current chopping.  $I_{\text{TRIP}}$  is ignored during  $T_{\text{BLANK}}$ , so the winding current may overshoot the trip level.

## 8.2.3 Application Curves



## 9 Power Supply Recommendations

### 9.1 Bulk Capacitance

Having an appropriate local bulk capacitance is an important factor in motor drive system design. It is generally beneficial to have more bulk capacitance, while the disadvantages are increased cost and physical size.

The amount of local capacitance needed depends on a variety of factors, including:

- The highest current required by the motor system
- The power supply's capacitance and ability to source current
- The amount of parasitic inductance between the power supply and motor system
- The acceptable voltage ripple
- The type of motor used (Brushed DC, Brushless DC, Stepper)
- The motor braking method

The inductance between the power supply and the motor drive system limits the rate current can change from the power supply. If the local bulk capacitance is too small, the system responds to excessive current demands or dumps from the motor with a change in voltage. When adequate bulk capacitance is used, the motor voltage remains stable and high current can be quickly supplied.

The data sheet generally provides a recommended value, but system-level testing is required to determine the appropriate sized bulk capacitor.

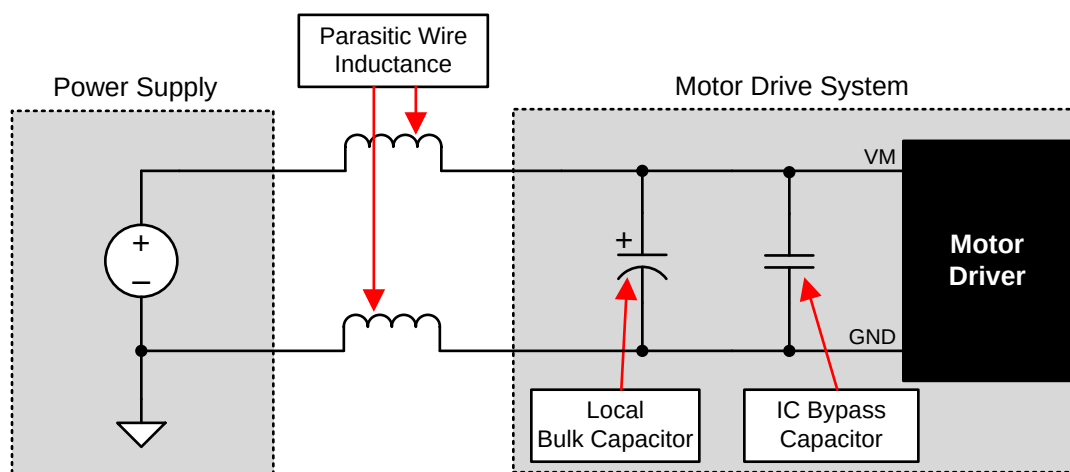


**Figure 23. Example Setup of Motor Drive System With External Power Supply**

The voltage rating for bulk capacitors should be higher than the operating voltage, to provide margin for cases when the motor transfers energy to the supply.

## 10 Layout

### 10.1 Layout Guidelines

The VM pin should be bypassed to GND using low-ESR ceramic bypass capacitors with a recommended value of 0.01- $\mu$ F rated for VM. This capacitor should be placed as close to the VM pin as possible with a thick trace or ground plane connection to the device GND pin. The VM pin must be bypassed to ground using an appropriate bulk capacitor. This component may be an electrolytic and should be located close to the DRV8711.

A low-ESR ceramic capacitor must be placed in between the VM and VCP pins. TI recommends a value of 1  $\mu$ F rated for 16 V. Place this component as close to the pins as possible.

A low-ESR ceramic capacitor must be placed in between the CP1 and CP2 pins. TI recommends a value of 0.1  $\mu$ F rated for VM. Place this component as close to the pins as possible.

Bypass VINT to ground with a 1- $\mu$ F ceramic capacitor rated 6.3 V. Place this bypass capacitor as close to the pin as possible.

Bypass V5 to ground with a 1- $\mu$ F ceramic capacitor rated 10 V. Place this bypass capacitor as close to the pin as possible.

## 10.2 Layout Example

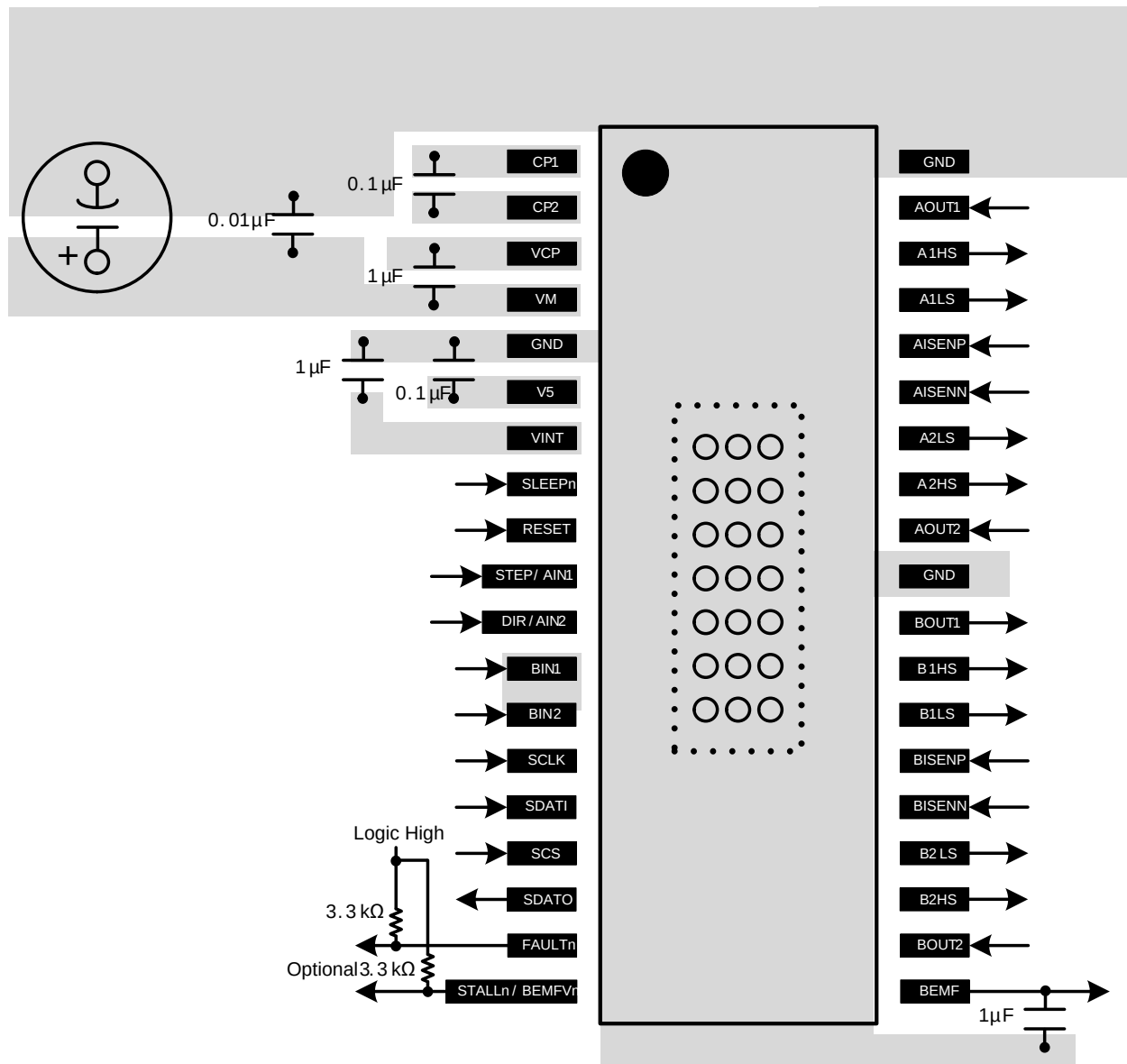


**Figure 24. Recommended Layout Example**

## 11 器件和文档支持

### 11.1 文档支持

#### 11.1.1 相关文档

请参阅如下相关文档：

- [《DRV8711 衰减模式设置优化》](#)
- [《DRV8711 快速启动和调优指南》](#)
- [《PowerPAD™ 散热增强型封装》](#)
- [《PowerPAD™ 速成》](#)

### 11.2 接收文档更新通知

要接收文档更新通知，请导航至德州仪器 TI.com.cn 上的器件产品文件夹。请单击右上角的通知我 进行注册，即可收到任意产品信息更改每周摘要。有关更改的详细信息，请查看任意已修订文档中包含的修订历史记录。

### 11.3 社区资源

下列链接提供到 TI 社区资源的连接。链接的内容由各个分销商“按照原样”提供。这些内容并不构成 TI 技术规范，并且不一定反映 TI 的观点；请参阅 TI 的 [《使用条款》](#)。

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**设计支持** TI 参考设计支持 可帮助您快速查找有帮助的 E2E 论坛、设计支持工具以及技术支持的联系信息。

### 11.4 商标

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All other trademarks are the property of their respective owners.

### 11.5 静电放电警告



这些装置包含有限的内置 ESD 保护。存储或装卸时，应将导线一起截短或将装置放置于导电泡棉中，以防止 MOS 门极遭受静电损伤。

### 11.6 Glossary

[SLYZ022](#) — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

## 12 机械、封装和可订购信息

以下页面包括机械、封装和可订购信息。这些信息是指定器件的最新可用数据。这些数据发生变化时，我们可能不会另行通知或修订此文档。如欲获取此产品说明书的浏览器版本，请参阅左侧的导航栏。

## PACKAGING INFORMATION

| Orderable part number       | Status<br>(1) | Material type<br>(2) | Package   Pins    | Package qty   Carrier | RoHS<br>(3) | Lead finish/<br>Ball material<br>(4) | MSL rating/<br>Peak reflow<br>(5) | Op temp (°C) | Part marking<br>(6) |
|-----------------------------|---------------|----------------------|-------------------|-----------------------|-------------|--------------------------------------|-----------------------------------|--------------|---------------------|
| <a href="#">DRV8711DCP</a>  | Obsolete      | Production           | HTSSOP (DCP)   38 | -                     | -           | Call TI                              | Call TI                           | -40 to 85    | DRV8711             |
| <a href="#">DRV8711DCPR</a> | Active        | Production           | HTSSOP (DCP)   38 | 2000   LARGE T&R      | Yes         | NIPDAU                               | Level-2-260C-1 YEAR               | -40 to 85    | DRV8711             |
| DRV8711DCPR.A               | Active        | Production           | HTSSOP (DCP)   38 | 2000   LARGE T&R      | Yes         | NIPDAU                               | Level-2-260C-1 YEAR               | -40 to 85    | DRV8711             |
| DRV8711DCPRG4               | Active        | Production           | HTSSOP (DCP)   38 | 2000   LARGE T&R      | Yes         | NIPDAU                               | Level-2-260C-1 YEAR               | -40 to 85    | DRV8711             |
| DRV8711DCPRG4.A             | Active        | Production           | HTSSOP (DCP)   38 | 2000   LARGE T&R      | Yes         | NIPDAU                               | Level-2-260C-1 YEAR               | -40 to 85    | DRV8711             |

<sup>(1)</sup> **Status:** For more details on status, see our [product life cycle](#).

<sup>(2)</sup> **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

<sup>(3)</sup> **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

<sup>(4)</sup> **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

<sup>(5)</sup> **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

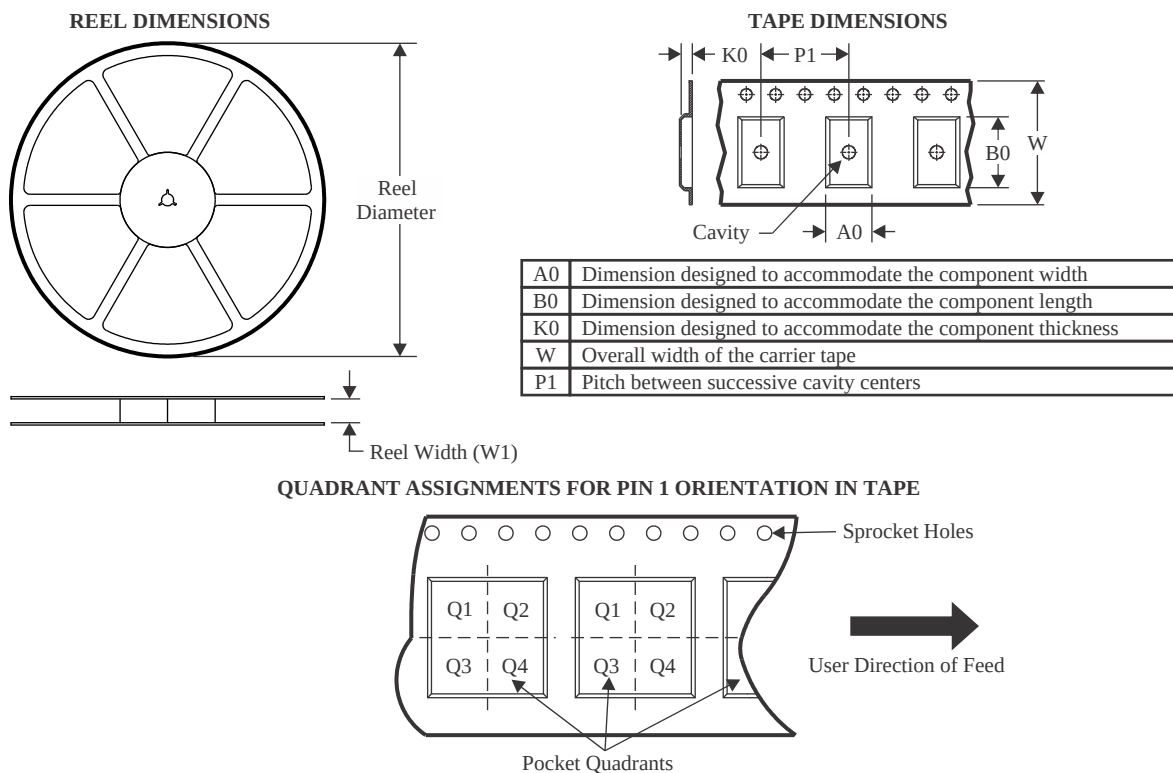
<sup>(6)</sup> **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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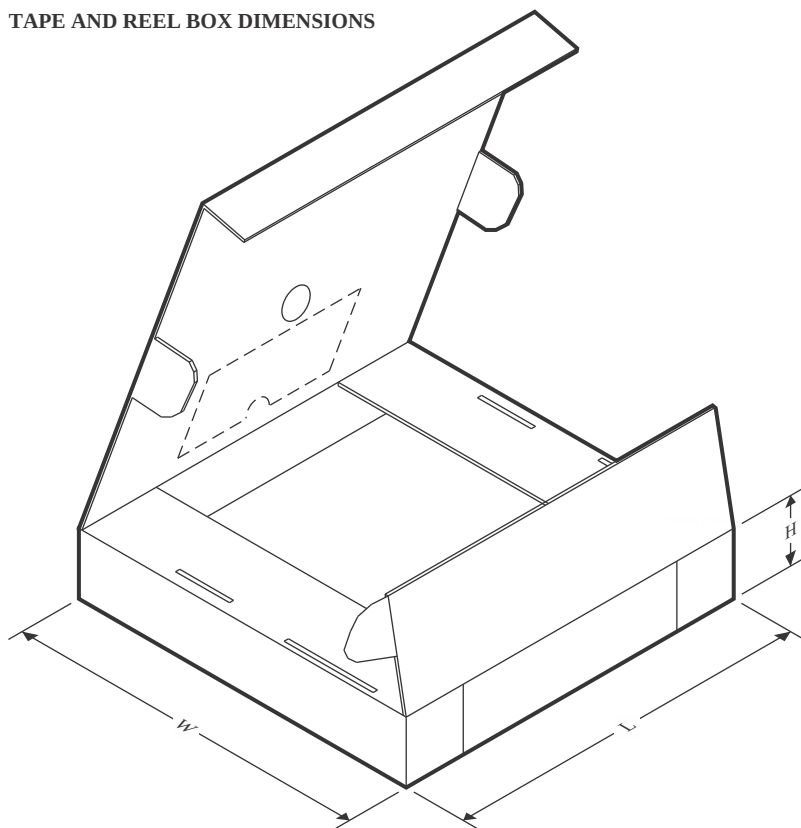
## TAPE AND REEL INFORMATION



\*All dimensions are nominal

| Device        | Package Type | Package Drawing | Pins | SPQ  | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|---------------|--------------|-----------------|------|------|--------------------|--------------------|---------|---------|---------|---------|--------|---------------|
| DRV8711DCPR   | HTSSOP       | DCP             | 38   | 2000 | 330.0              | 16.4               | 6.9     | 10.2    | 1.8     | 12.0    | 16.0   | Q1            |
| DRV8711DCPRG4 | HTSSOP       | DCP             | 38   | 2000 | 330.0              | 16.4               | 6.9     | 10.2    | 1.8     | 12.0    | 16.0   | Q1            |

## TAPE AND REEL BOX DIMENSIONS



\*All dimensions are nominal

| Device        | Package Type | Package Drawing | Pins | SPQ  | Length (mm) | Width (mm) | Height (mm) |
|---------------|--------------|-----------------|------|------|-------------|------------|-------------|
| DRV8711DCPR   | HTSSOP       | DCP             | 38   | 2000 | 350.0       | 350.0      | 43.0        |
| DRV8711DCPRG4 | HTSSOP       | DCP             | 38   | 2000 | 350.0       | 350.0      | 43.0        |

## GENERIC PACKAGE VIEW

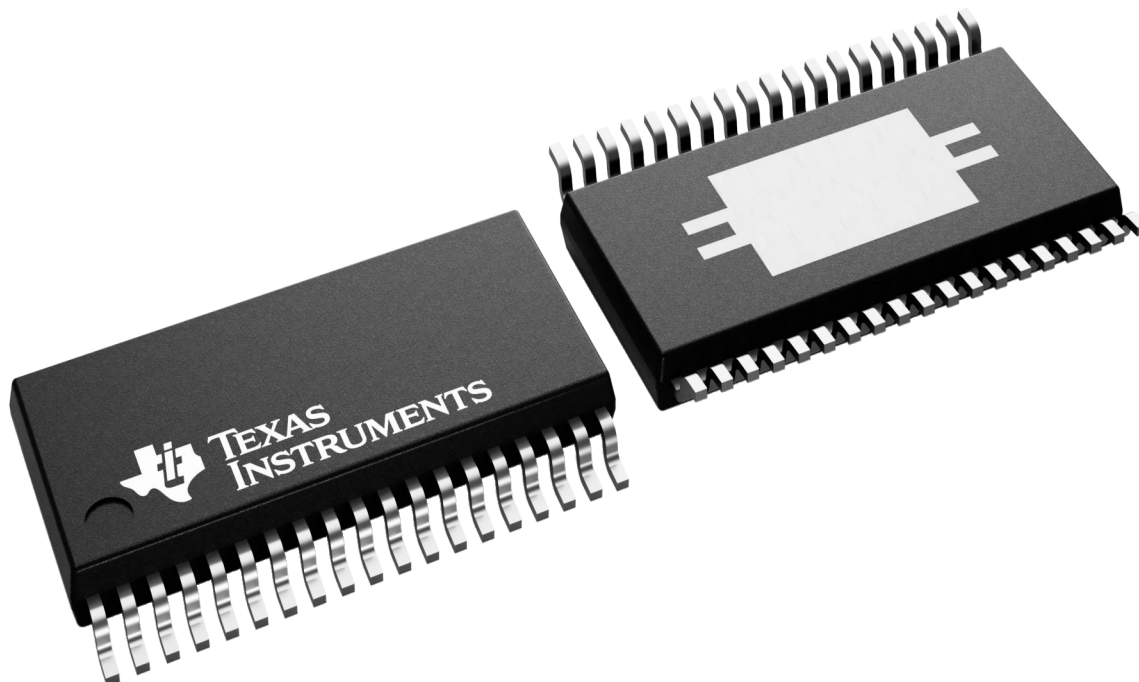
**DCP 38**

**PowerPAD TSSOP - 1.2 mm max height**

4.4 x 9.7, 0.5 mm pitch

SMALL OUTLINE PACKAGE

This image is a representation of the package family, actual package may vary.  
Refer to the product data sheet for package details.



4224560/B



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PowerPAD is a trademark of Texas Instruments.

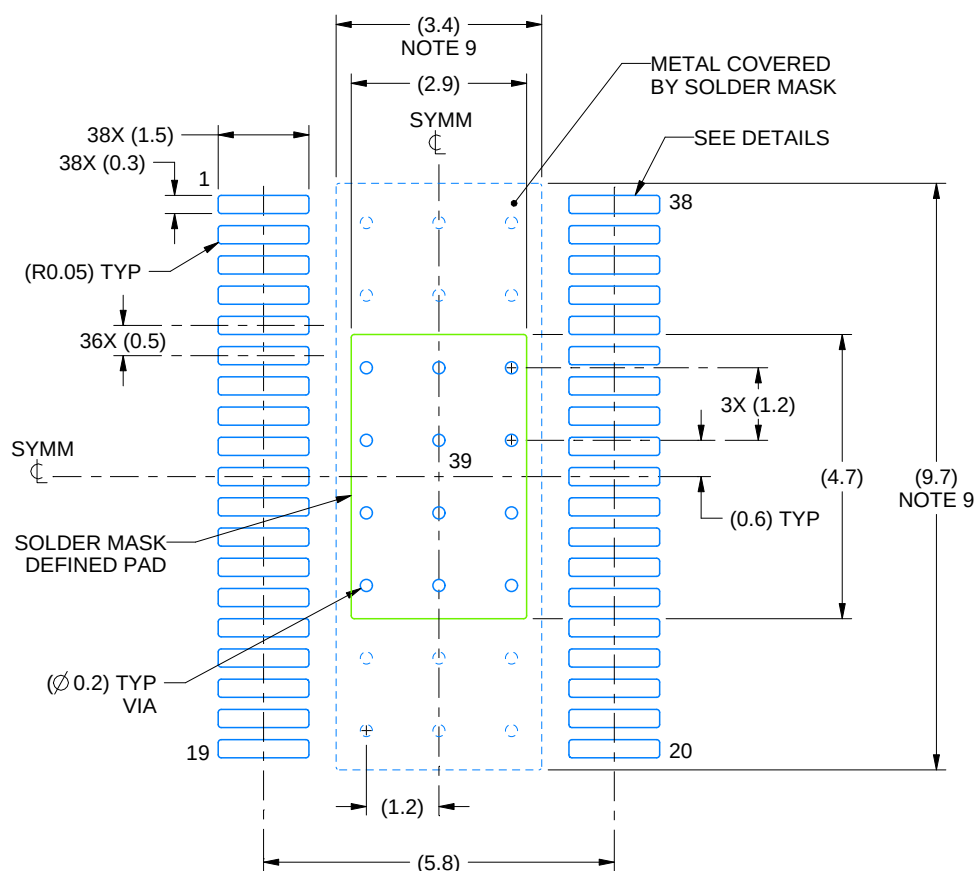
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. Reference JEDEC registration MO-153.
5. Features may differ or may not be present.

# EXAMPLE BOARD LAYOUT

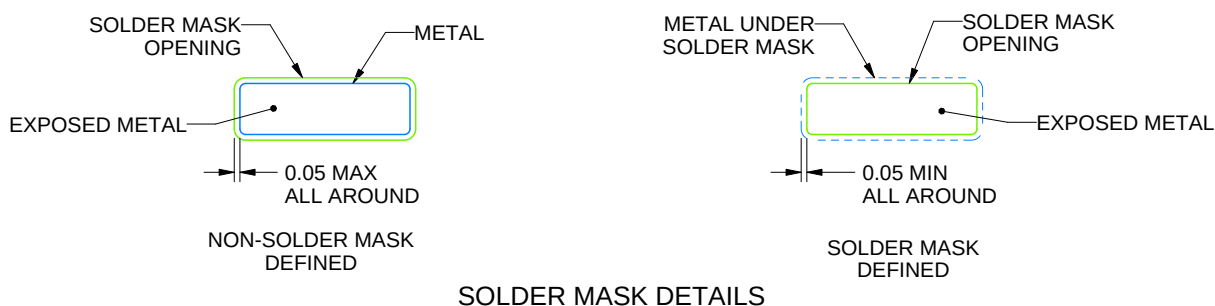
DCP0038A

PowerPAD™ TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



LAND PATTERN EXAMPLE  
EXPOSED METAL SHOWN  
SCALE: 8X



SOLDER MASK DETAILS

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NOTES: (continued)

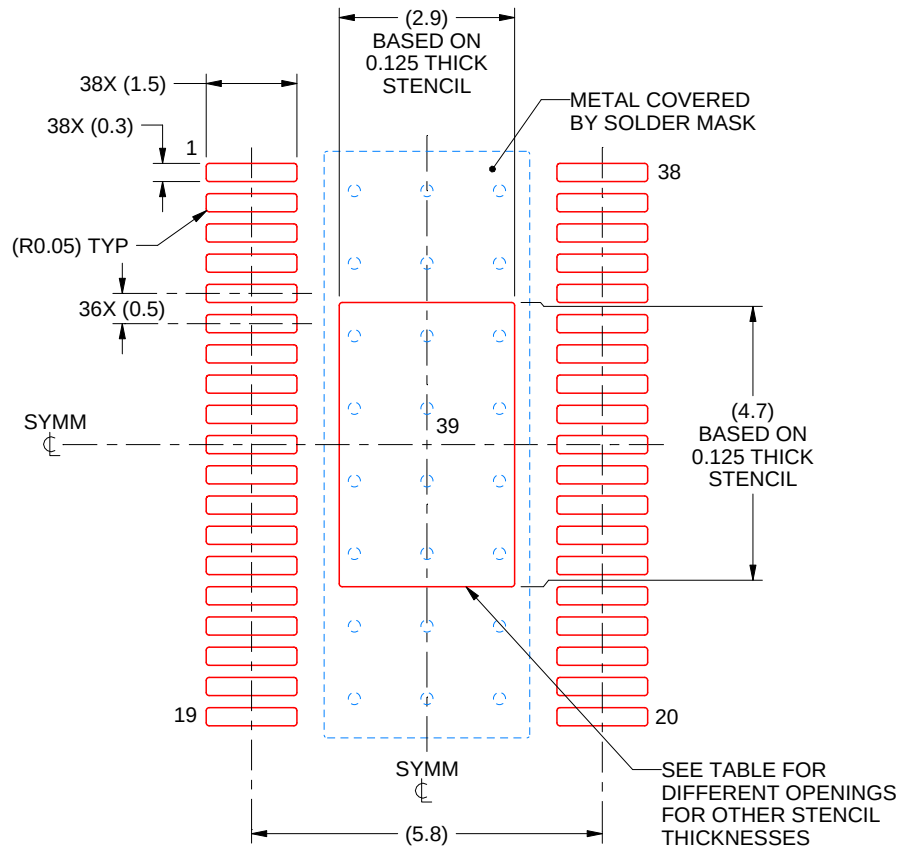
6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
8. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature numbers SLMA002 ([www.ti.com/lit/slma002](http://www.ti.com/lit/slma002)) and SLMA004 ([www.ti.com/lit/slma004](http://www.ti.com/lit/slma004)).
9. Size of metal pad may vary due to creepage requirement.
10. Vias are optional depending on application, refer to device data sheet. It is recommended that vias under paste be filled, plugged or tented.

# EXAMPLE STENCIL DESIGN

DCP0038A

PowerPAD™ TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



**SOLDER PASTE EXAMPLE**  
 BASED ON 0.125 mm THICK STENCIL  
 SCALE: 8X

| STENCIL THICKNESS | SOLDER STENCIL OPENING |
|-------------------|------------------------|
| 0.1               | 3.24 X 5.25            |
| 0.125             | 2.90 X 4.70 (SHOWN)    |
| 0.15              | 2.65 X 4.29            |
| 0.175             | 2.45 X 3.97            |

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NOTES: (continued)

11. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
12. Board assembly site may have different recommendations for stencil design.

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